



# Unit-3

LASER

(Light Amplification due to stimulated emission of  
Radiations)

### MEDICINE AND HEALTHCARE

- Bloodless surgery
- Kidney stone treatment
- Dermatology
- Ophthalmology
- Dentistry
- Neurology
- Tissue repairs
- Cosmetology

### DEFENCE AND SECURITY

- Marking targets
- Guiding ammunitions
- Missiles
- Electro-optical counter measures
- Blinding troops

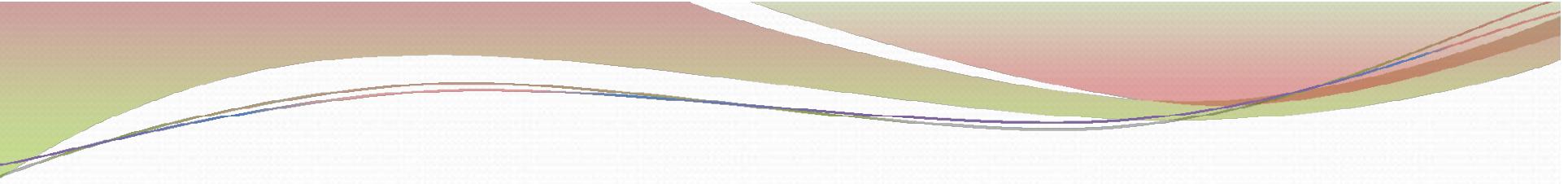
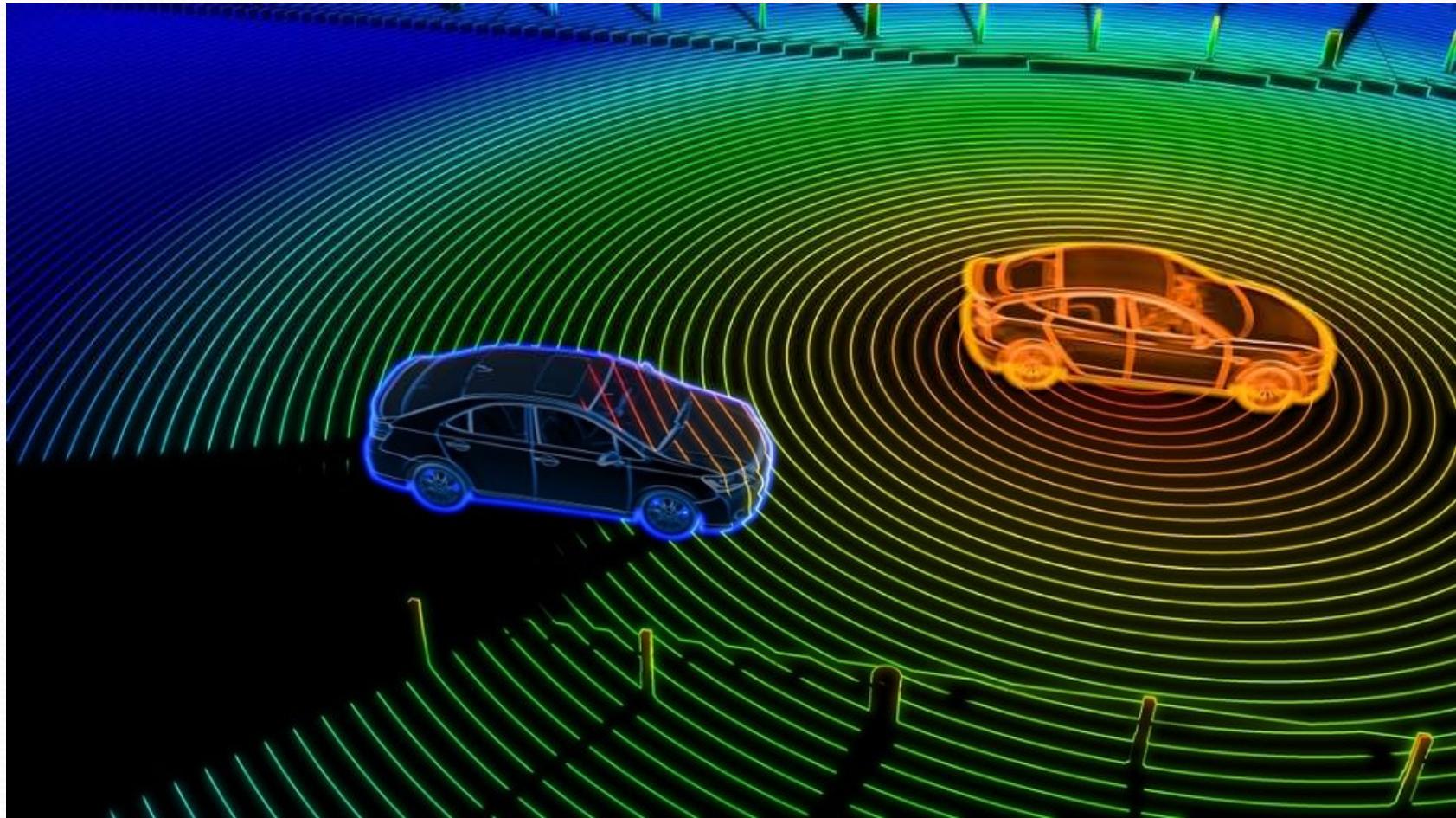
**LASERS**

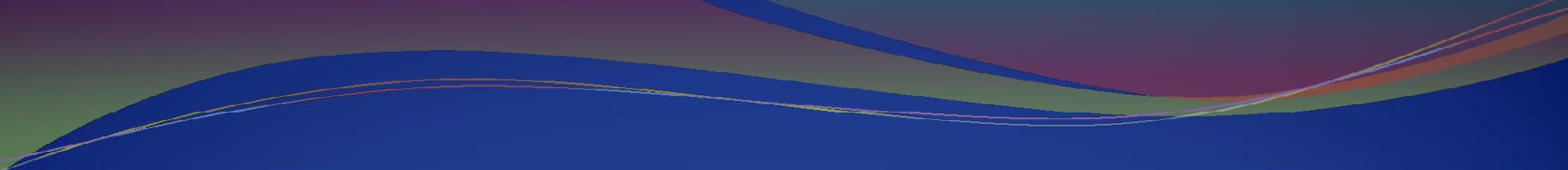
### COMMERCIAL AND ENTERTAINMENT

- Laser printers
- Optical disks
- Barcode scanners
- Thermometers
- Laser pointers
- 3D holograms
- Laser light shows
- Decoration

### ENFORCEMENT AND SCIENTIFIC/ TECH RESEARCH

- Laser fingerprint detection
- Forensic science
- Spectroscopy
- Laser ablation
- Laser scattering microscopy
- Metrology





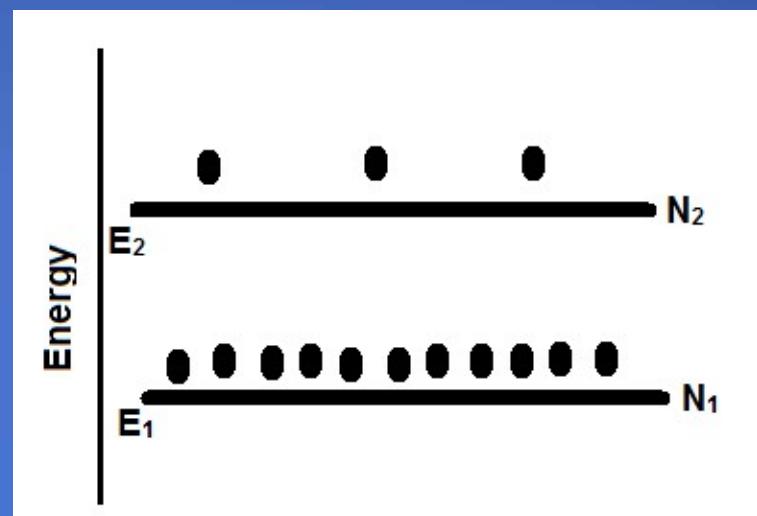
# **Interaction of Radiation with Mattar**

- 1) Absorption**
- 2) Spontaneous Emission**
- 3) Stimulated Emission**

# Thermal Equilibrium

- ❖ Material medium can be considered as composed of identical atoms characterized by specific system of energy levels
- ❖ These energy levels are identical for all atoms in the medium.
- ❖ Population : The number of atoms per unit volume that occupy a given energy level is called the population of that energy level.

- Assumption: Particular medium has atoms, which are characterized by only two energy levels.
- $E_1$  be ground level with population  $N_1$
- $E_2$  be Exited level with population  $N_2$



At thermal Equilibrium, the population at the energy levels can be found with Boltzmann Law

$$N_1 = e^{\frac{-E_1}{KT}}$$

$$N_2 = e^{\frac{-E_2}{KT}}$$

Relative population  $N_2 / N_1$  is given by

$$\frac{N_2}{N_1} = e^{\frac{-(E_2 - E_1)}{KT}}$$

- ✓  $N_2 / N_1$  depends on
  - a) Temperature
  - b)  $(E_2 - E_1)$

### **Effect of Temperature**

$$(E_2 - E_1) = 10.21 \text{ eV}$$

$$T = 300 \text{ K}$$

$$\frac{N_2}{N_1} = e^{\frac{-(10.21)}{0.025}} \approx 0$$

$$T = 6000 \text{ K}$$

$$\frac{N_2}{N_1} = e^{\frac{-(10.21)}{0.516}} \approx \frac{4}{10^{10}}$$

Even at very high temperatures the fraction of excited atoms is very small

- ❖ Under normal conditions( at Thermal Equilibrium)

$$N_1 \gg N_2$$

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Even at very high temperatures the fraction of excited atoms is very small

❖ Under normal conditions( at Thermal Equilibrium)

$$N_1 \gg N_2$$

As  $T \rightarrow \infty$

$$N_2 / N_1 = e^0 = 1$$

$$N_1 = N_2$$

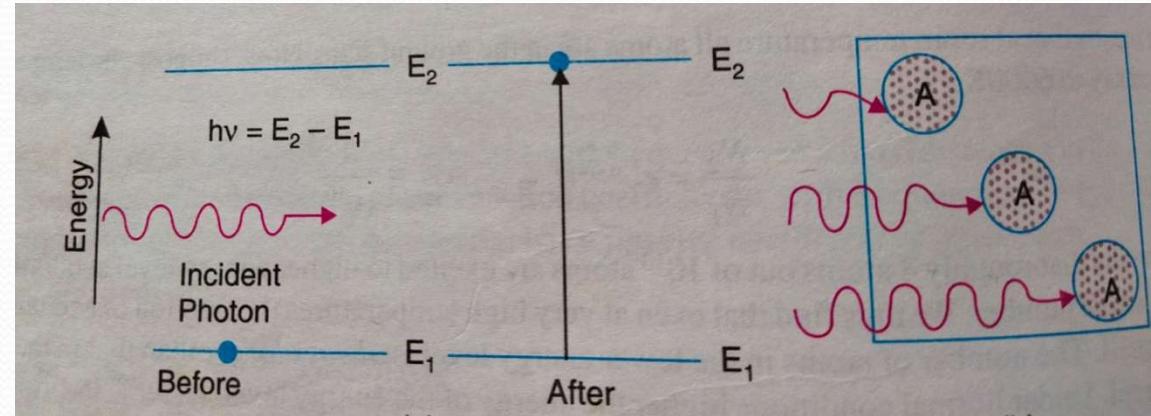
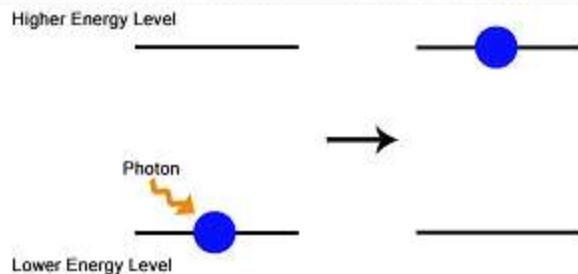
**As Long As System is in Thermal Equilibrium the population of higher energy level cannot exceed the population of lower energy level.**

# Interaction of Light with Matter

When Photons travel through medium three different optical processes are likely to occur:

- 1) Absorption
- 2) Spontaneous Emission
- 3) Stimulated emission

# Absorption



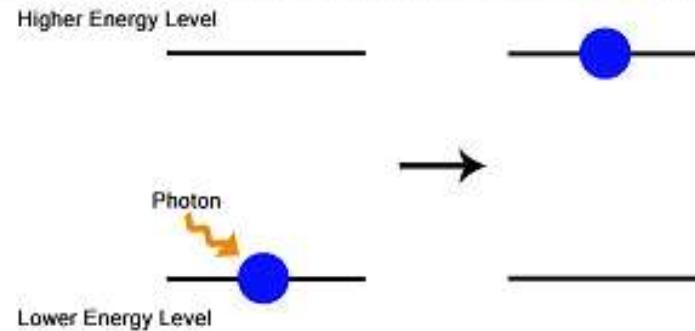
- When Photon of energy  $h\nu$  is incident on an atom. It may impart its energy to the atom.
- The atom residing in the lower energy state  $E_1$  may absorb the incident photon and make transition to higher energy state  $E_2$ .
- Transition is called absorption transition or induced absorption.



A is atom in lower energy state

$A^*$  is atom in excited state

# Absorption



Probability of absorption transition is  $P_{12}$

- a) Directly proportional to number of atoms in ground state (  $N_1$  )
- b) Photon density  $\rho(v)$

$$P_{12} = B_{12} \rho(v)$$

Number of absorption transitions in time  $\Delta t$

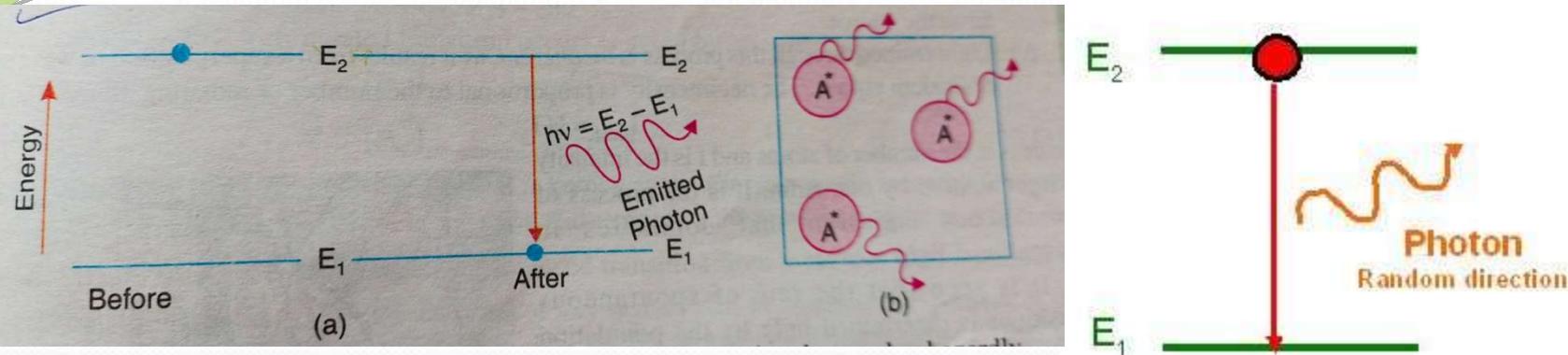
$$N_{ab} = B_{12} N_1 \rho(v) \Delta t$$

$B_{12}$  = Einstein coefficient for induced absorption ( it indicates the probability of occurrence of induced transition from level  $1 \rightarrow 2$  )

# Spontaneous Emission



## Spontaneous emission



- ❖ An atom in excited state ( $E_2$ ) make transition to Lower energy state ( $E_1$ ) by emitting a photon.
- ❖ The excited atom in the state  $E$  may return to lower energy state  $E$  on its own out of natural tendency to attain minimum potential condition.
- ❖ During transition the excess energy is released as a photon of energy .

$$h\nu = E_2 - E_1$$

- ❖ This process in which photon emission occurs without any external impetus is called spontaneous emission.



**A** is atom in lower energy state

**$A^*$**  is atom in excited state

**Probability of spontaneous emission transition is**

$$P_{21}$$

**a) Depends only on properties of energy states  $E_2$  and  $E_1$**

$$P_{12} = A_{21}$$

**❖ Number of spontaneous transitions in time  $\Delta t$**

$$N_{sp} = A_{21} N_2 \Delta t$$

**$A_{21}$  = Einstein coefficient of spontaneous emission ( it indicates the probability of occurrence of spontaneous transition from level**

**$2 \rightarrow 1$**

**$A_{21}$  is a Characteristics of energy states of an atom**

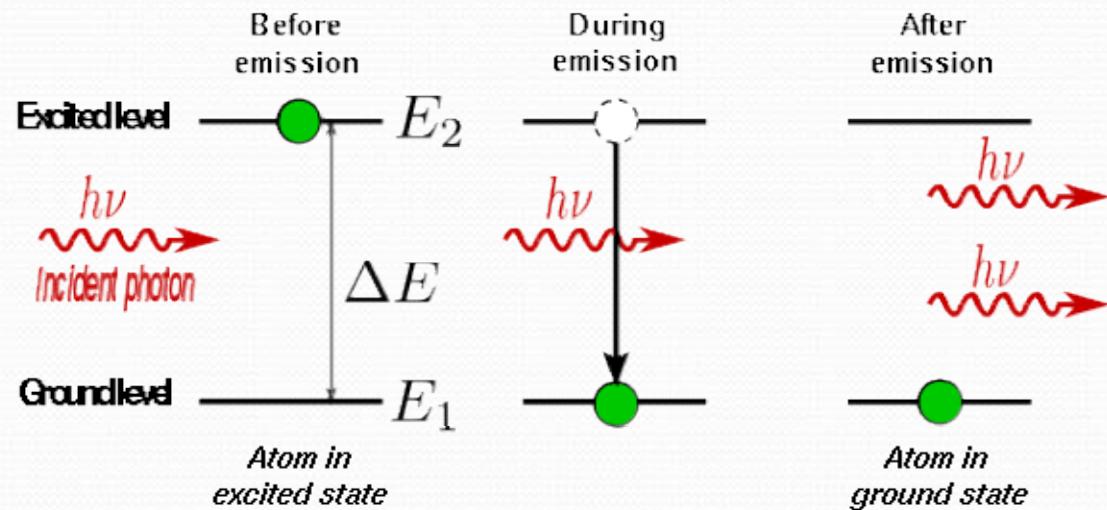
**1/  $A_{21}$  represents the lifetime of upper state against spontaneous transition to lower state.**

# Characterstics of Spontaneous transitions

- ❖ The process of spontaneous emission is essentially probabilistic in nature and is not amenable to control from outside
- ❖ The instant of transition, direction of propagation, the initial phase and plane of polarization of each photon are all random.
- ❖ The light resulting from this process is not monochromatic
- ❖ Different atoms in source emits photons in all different directions, the light spreads in all directions around the source. Light intensity goes on decreasing rapidly with distance from the source
- ❖ Light emitted through this process is incoherent.
- ❖ Net Intensity is Proportional to number of radiating atoms

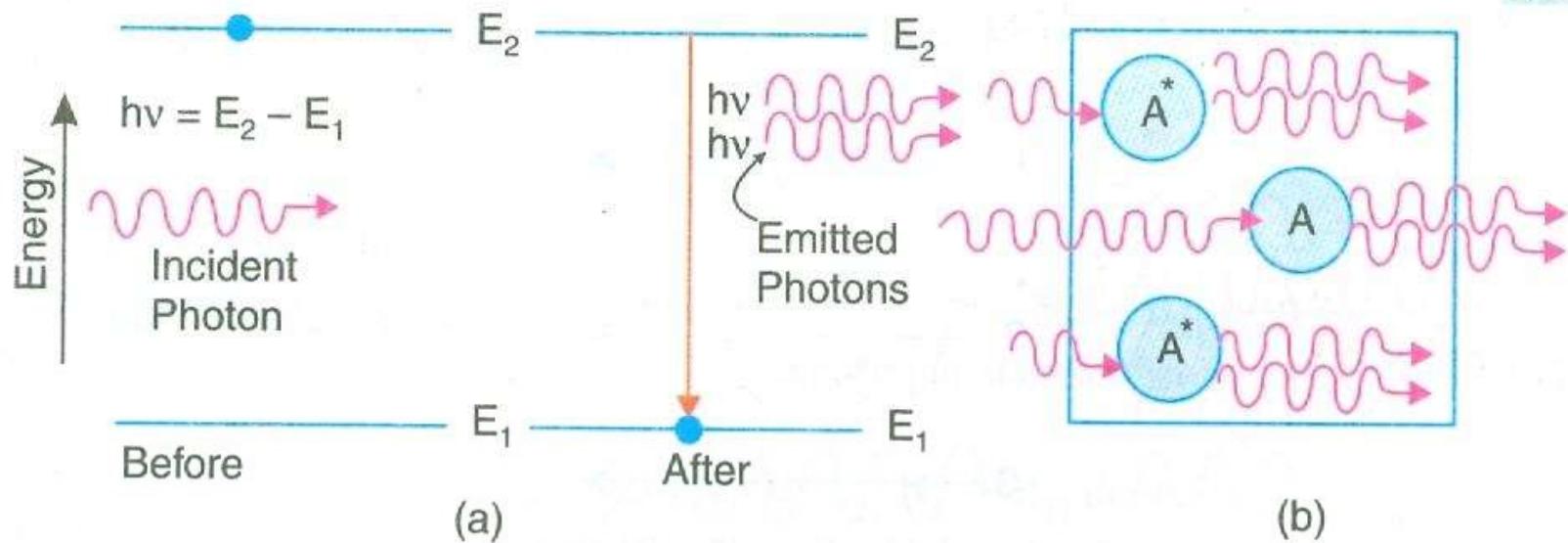
$$I_{\text{net}} = NI$$

# Stimulated Emission



$$E_2 - E_1 = \Delta E = h\nu$$

The Phenomenon of forced photon emission by an exited atom due to the action of an external agency is called stimulated emission or induced emission.



Stimulated emission (a) emission process.  
 (b) Material emits photons in a coordinated manner.

# Stimulated Emission

stimulated transition may be represented as



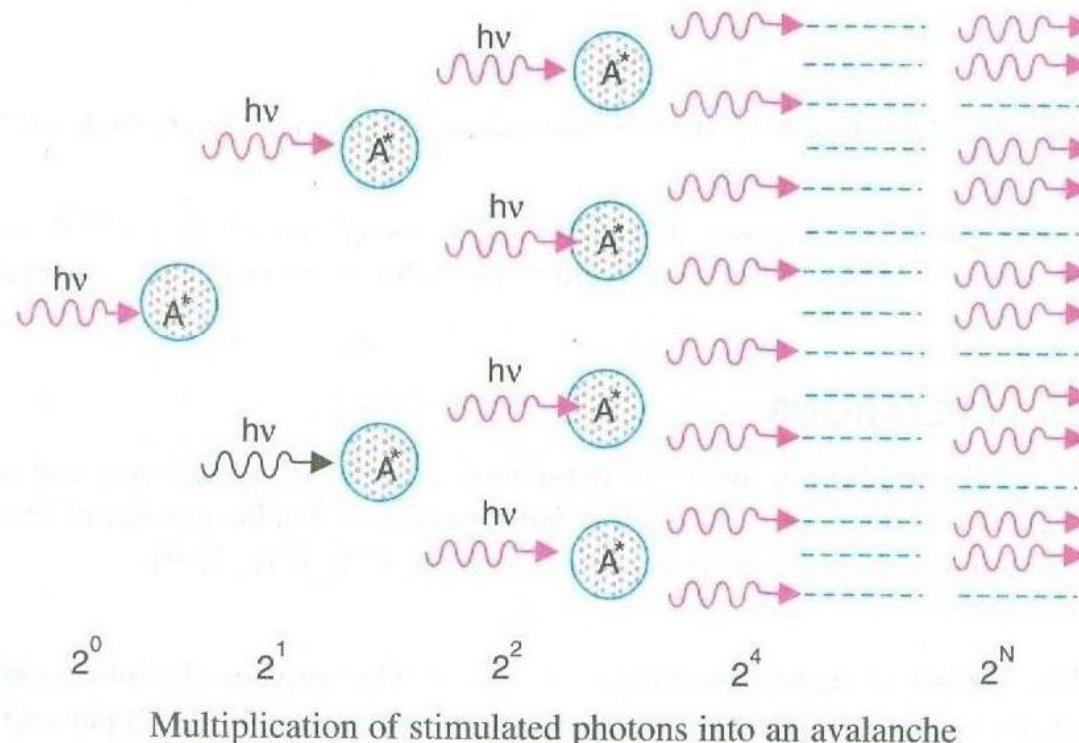
A= an atom in lower state

$A^*$ = excited atom

The number of stimulated transitions  $N_{st}$  occurring in the material during the  $\Delta t$  may be given by

$$N_{st} = B_{21} N_2 \rho(v) \Delta t$$

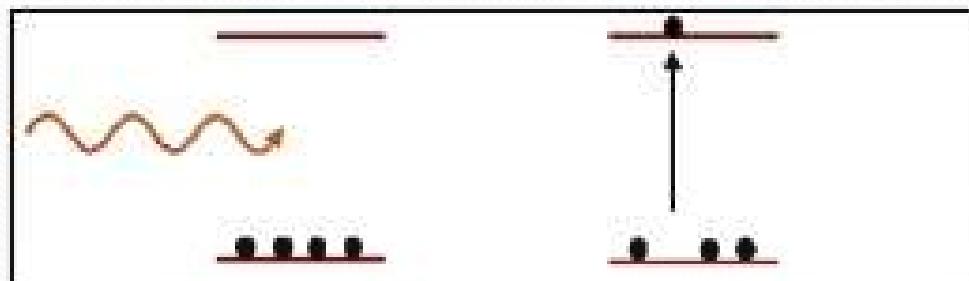
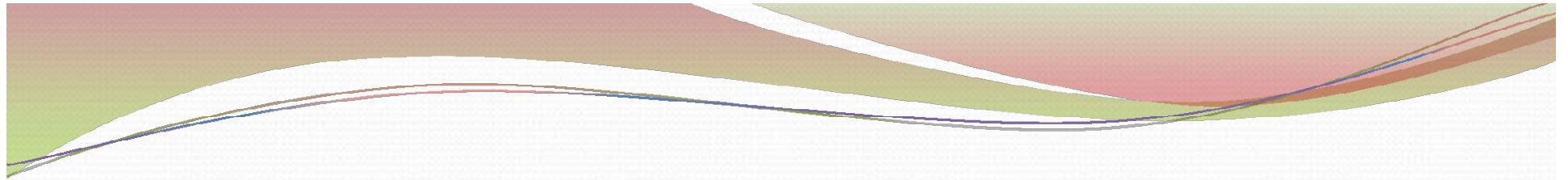
# Multiplication of stimulated photons



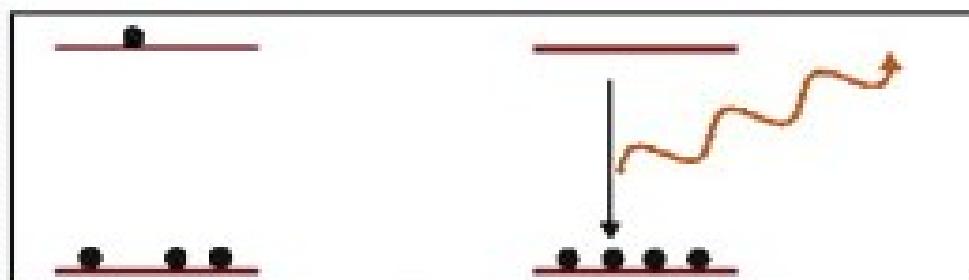
$$I_{\text{total}} = 2^N I$$

# Characterstics of Stimulated transitions

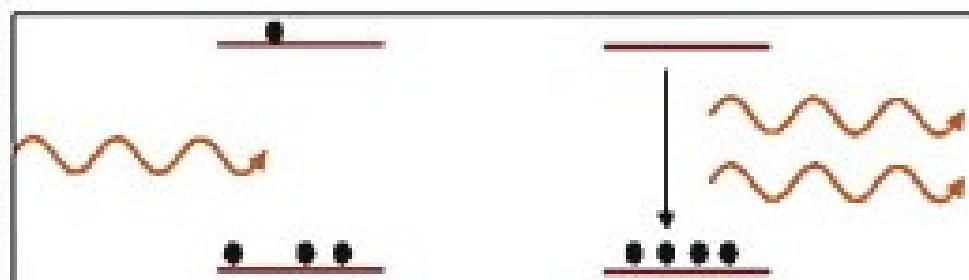
1. Not a Random Process
2. Amenable to control from outside
3. The photons emitted in the process travel in same direction as that of stimulating photon.
4. The emitted photon has same frequency, phase and plane of polarization as that of stimulating photon.
5. Multiplication of photon takes place.
6. electromagnetic waves of extremely high amplitude could be generated by the combined stimulated emmisions from a large samples of atoms leading to amplification of light
7. The process of stimulated emission is the key to the operation of a laser.



Absorption



Spontaneous  
Emission



Stimulated  
Emission

# Conditions for Light Amplification

Light Amplification requires stimulated emission to dominate spontaneous emission.

$$\frac{\text{Stimulated emission}}{\text{Spontaneous emission}} = \frac{B_{21}N_2\rho(\nu)}{A_{21}N_2} = \frac{B_{21}}{A_{21}}\rho(\nu)$$

For Stimulated emissions to dominate Spontaneous Transition

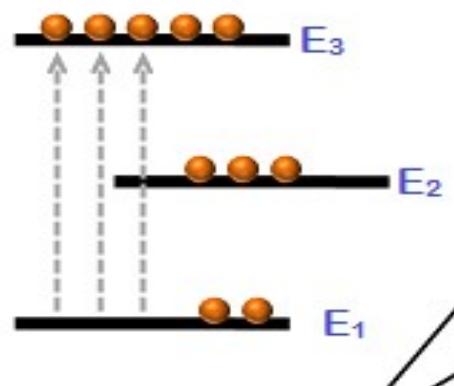
- a) Lifetime of energy state should be high
- b)  $\rho(\nu)$  is very large

## Condition for stimulated emission to dominate absorption transition

$$\frac{\text{Stimulated emission}}{\text{Absorption transition}} = \frac{B_{21} N_2 P(v)}{B_{12} N_1 P(v)} = \frac{N_2}{N_1}$$

$$B_{12} = B_{21}$$

For Stimulated emission to dominate Absorption transition  
 $N_2 >> N_1$



## Meeting Requirements for Stimulated emission

- Existence of Metastable state
- Population Inversion
- High Radiation density

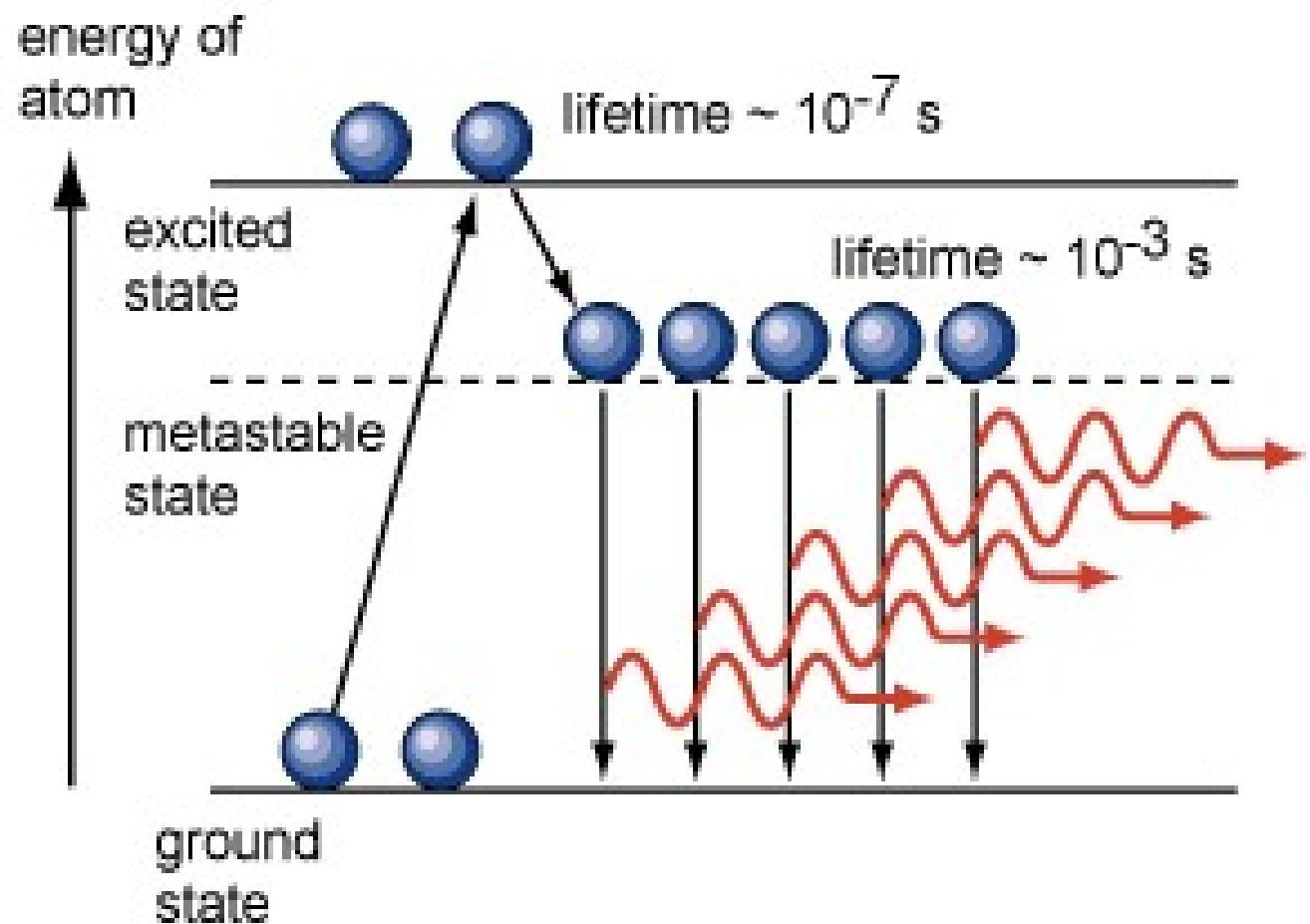
# Meeting Requirements for Stimulated emission

Existence of Metastable States: Exited state with large lifetime of the order millisecond to microsecond duration.

- In order to establish the condition of population inversion, the excited atoms are required to ‘wait’ at the upper energy level till a large number of atoms accumulate at that level, it is necessary that the excited state has a longer lifetime. *A metastable state is such a state with lifetime of the order of  $10^{-3}$ s to  $10^{-6}$ s.*
- *There could be no population inversion and hence no laser action, if metastable states do not exists*

# Metastable States

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- *There could be no population inversion and hence no laser action, if metastable states do not exists*



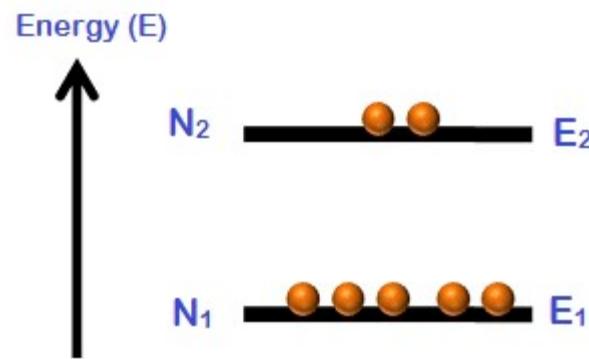
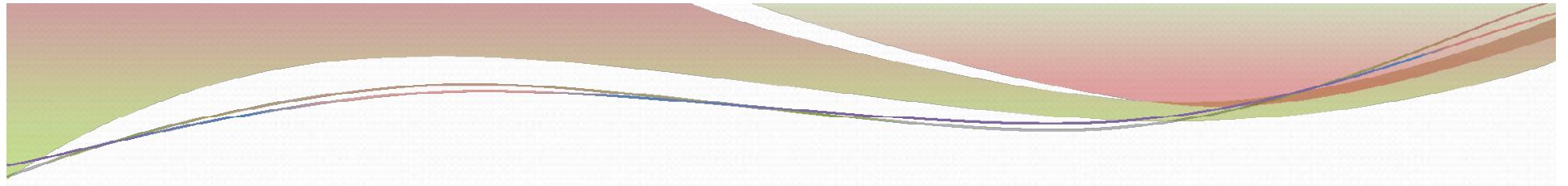
# Conditions for Stimulated emission

## Population Inversion

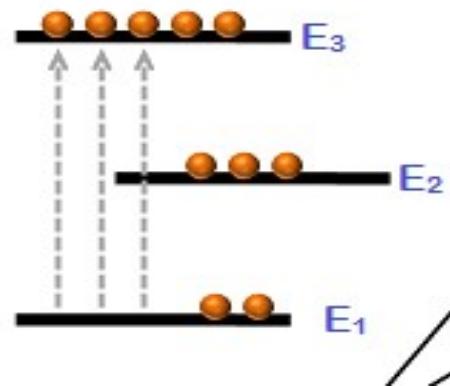
- $N_2 > N_1$       $N_2$ - no. of atoms in  $E_2$   
                     $N_1$ - no. of atoms in  $E_1$

The condition in which there are more number of atoms in exited state as compared to lower energy state is called population inversion.

This is non equilibrium state and exists for short time.



Normal Energy State  
Equilibrium State



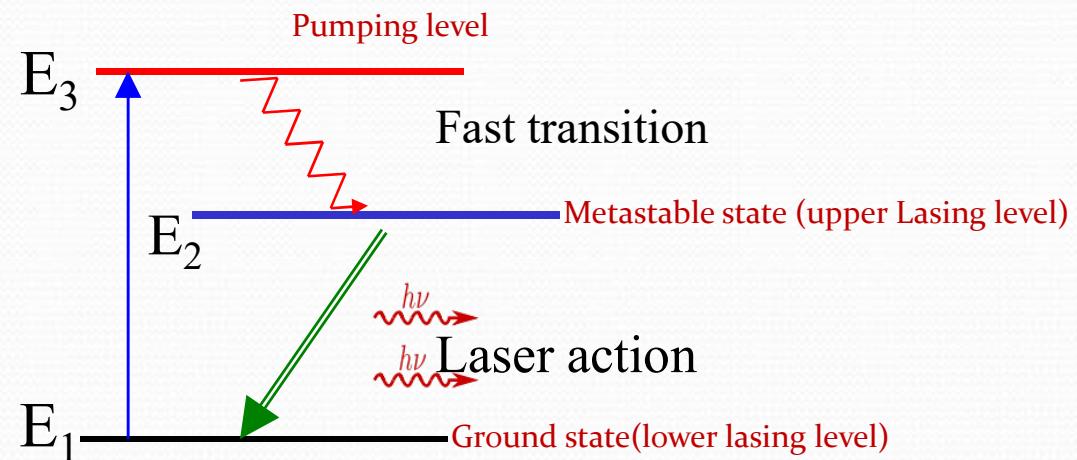
Population Inversion

# Population Inversion

- ❖ The population Inversion is non equilibrium condition of material in which population of upper energy level  $N_2$  momentarily exceeds population of lower energy level  $N_1$
- ❖ It is also referred to as negative temperature state.
- ❖ Population inversion is negative temperature state.

# The principal Pumping Schemes: Laser Operation

## Three level system

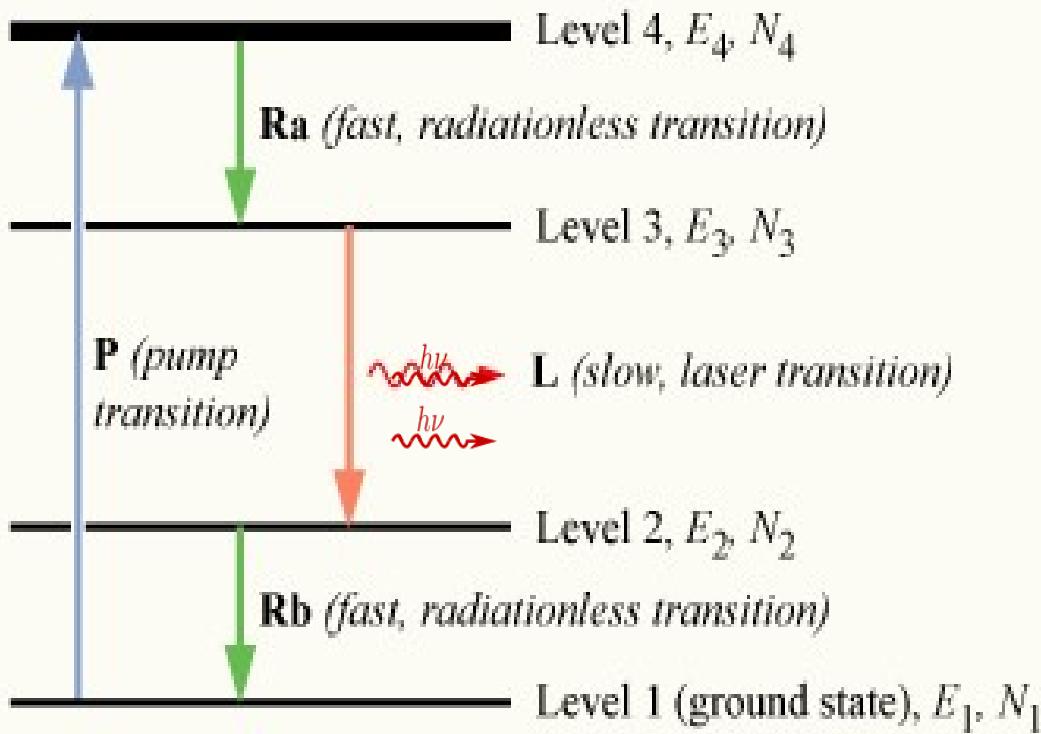


### Possible Transitions

- $E_1 \rightarrow E_3$  Pumping
- $E_3 \rightarrow E_2$  Spontaneous emission.
- $E_2 \rightarrow E_1$  Stimulated emission.
- Population inversion between states  $E_2$  and  $E_1$
- State  $E_2$  is a metastable state

# The principal Pumping Schemes: Laser Operation

## Four level system



### Possible Transitions

- $E_1 \rightarrow E_4$  Pumping
- $E_4 \rightarrow E_3$ ,  $E_2 \rightarrow E_1$  spontaneous emission.
- $E_3 \rightarrow E_2$  Stimulated emission.
- Population inversion between states  $E_3$  and  $E_2$
- State  $E_3$  is a metastable state

## Two Level System

In a simple two-level system, it is not possible to obtain a population inversion with optical pumping because the rate of absorption becomes equal to rate of

### **TWO LEVEL LASER NOT POSSIBLE**

Optical pumping will at most only achieve equal population of a two-level system. This is because the probabilities for raising an electron to the upper level and inducing the decay of an electron to the lower level (simulated emission) *are exactly the same!* In other words, when both levels are equally populated, the numbers of electrons "going up" and "down" will be the same, so you cannot achieve population inversion which is required for lasers.

The solution is to use a *third metastable level*. The pumping will be between the other two, but electrons in the upper energy level will quickly decay into the metastable level, leaving the upper level practically unpopulated at all times. The transition from the metastable level to the ground level has a different frequency: the laser frequency. The pumping frequency is between upper level and the ground level, so the pumping is off-resonant to the laser transition and will, thus, not trigger stimulated emission.

# Two level Pumping Scheme

According to Heisenbergs Uncertainty Principle

$$\Delta E \Delta t \geq h/2\pi$$

$\Delta E$  is band width

$\Delta t$  is time span for which atom stays in upper energy state

$\Delta t$  should be longer for achieving population inversion and if  $\Delta t$  is longer  $\Delta E$  is smaller that is  $E_2$  is narrow, enough atoms cannot be raised to level  $E_2$  and hence population inversion cannot be achieved.

# Components Of Laser

The essential components of laser

- ✓ Active Medium
- ✓ Pump
- ✓ Optical Resonator Cavity

# Active Medium

Active Medium is medium in which light amplification takes place

Active Medium= Active Centers + Host Atoms

Active Centers when exited reaches the state of population inversion and promotes stimulated emissions leading to light amplification

Host Atoms supports active centers. Active centres are dispersed in host atoms(bulk)

# Pump

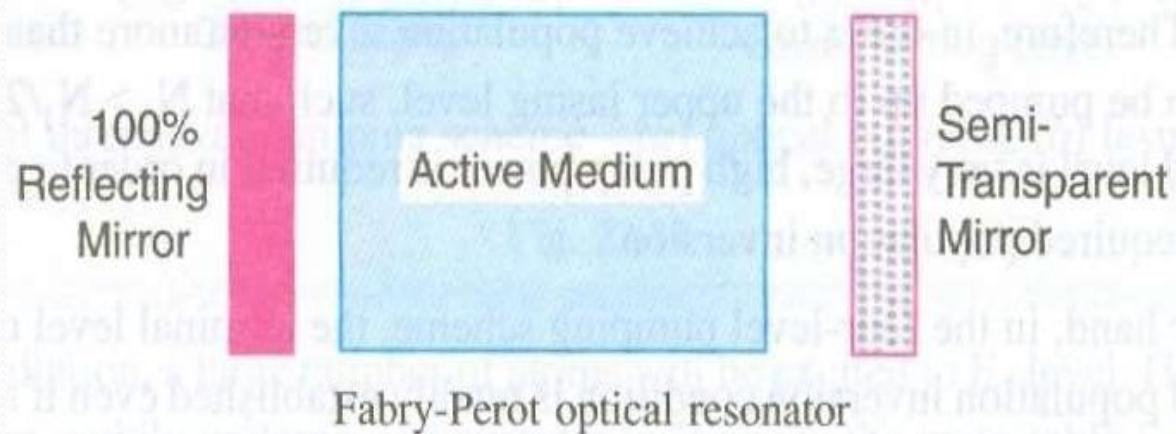
Pumping is the process of supplying energy to the laser medium with the view to transfer it into the state of population inversion.

Pump is agency which supplies energy

## Different types of Pumping:

- Optical Pumping (Light Source, such Flash Discharge tube)-----employed in solid state lasers
- Electric Discharge methods(Electric field causes ionization of medium and raises it to exited state)-----  
---employed in gas lasers
- Direct Conversion of electrical energy into light energy-----Employed in semiconductor lasers

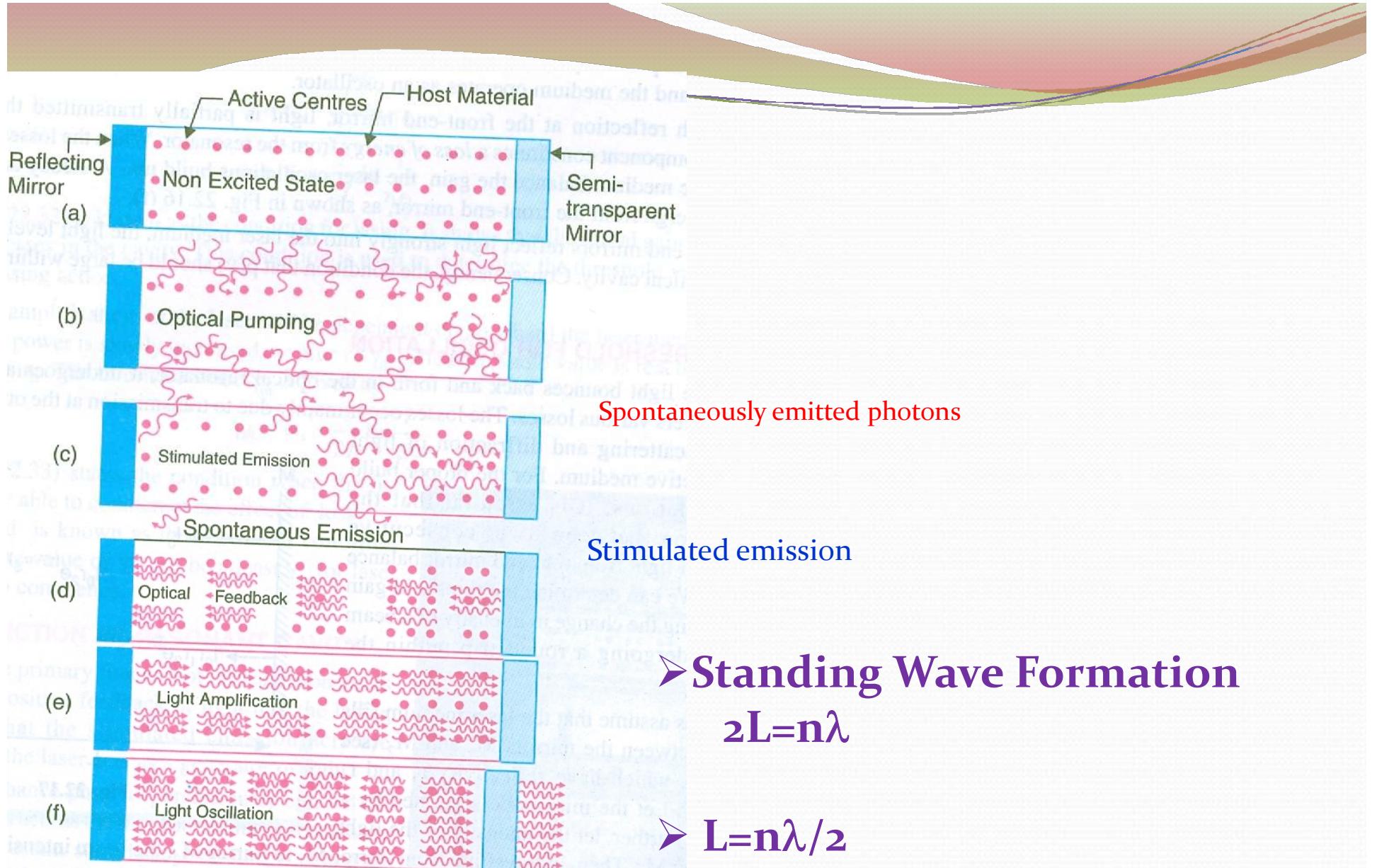
# Optical Resonator Cavity

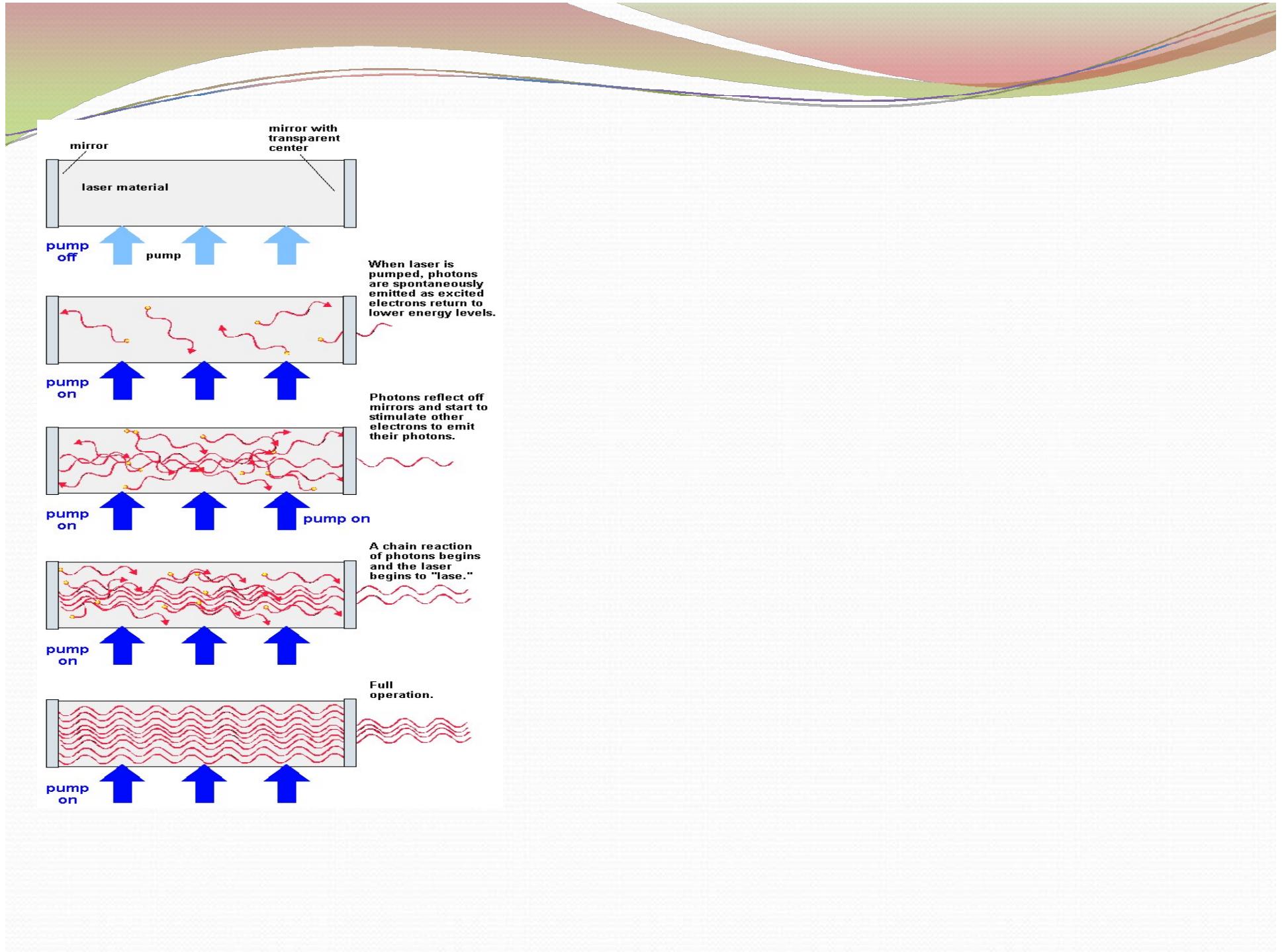


- A pair of optically plane parallel mirrors , enclosing laser medium in between them is known as an optically resonator cavity.
- One mirror is partially reflecting other mirror is fully reflecting

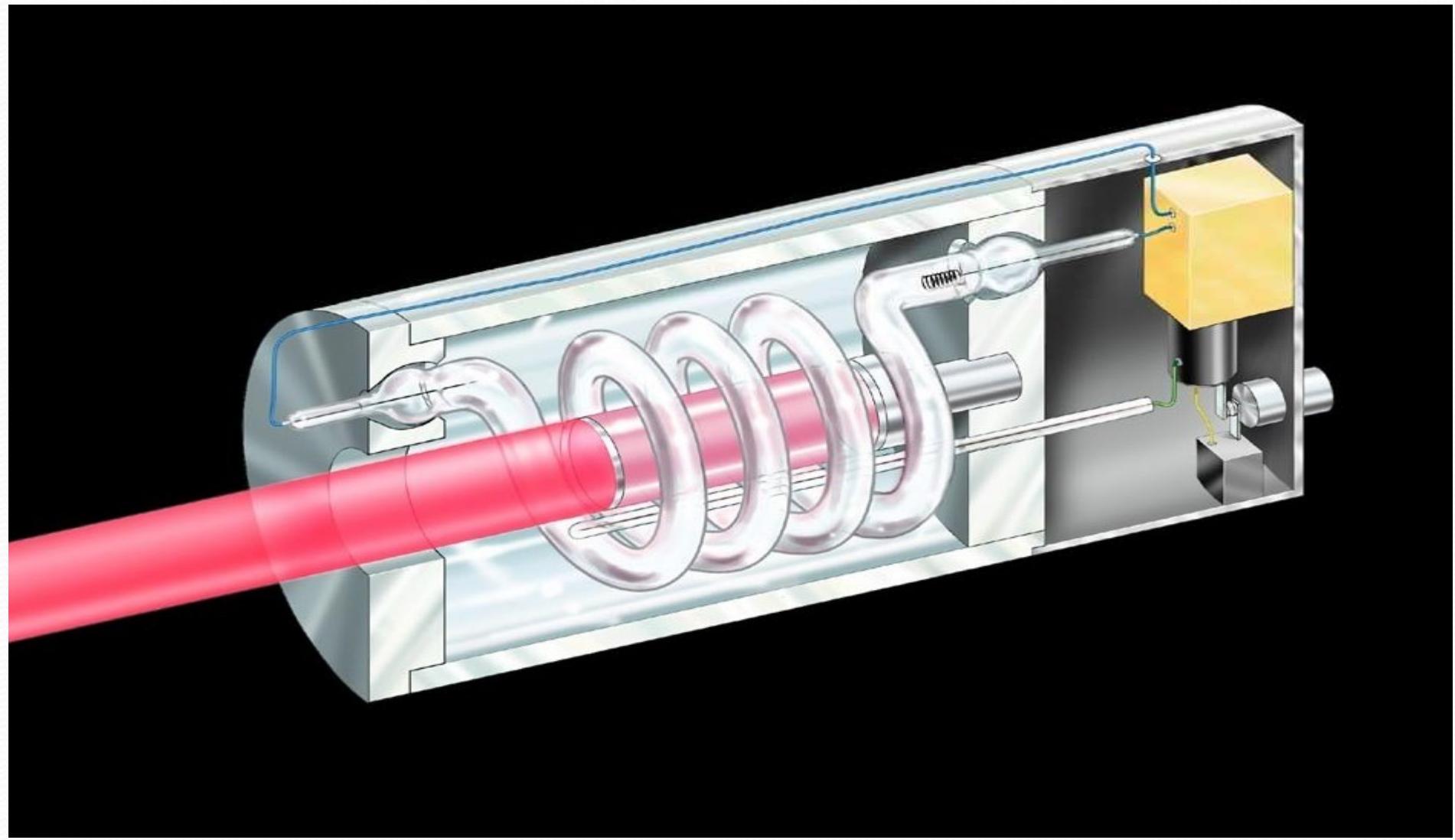
# Optical Resonator

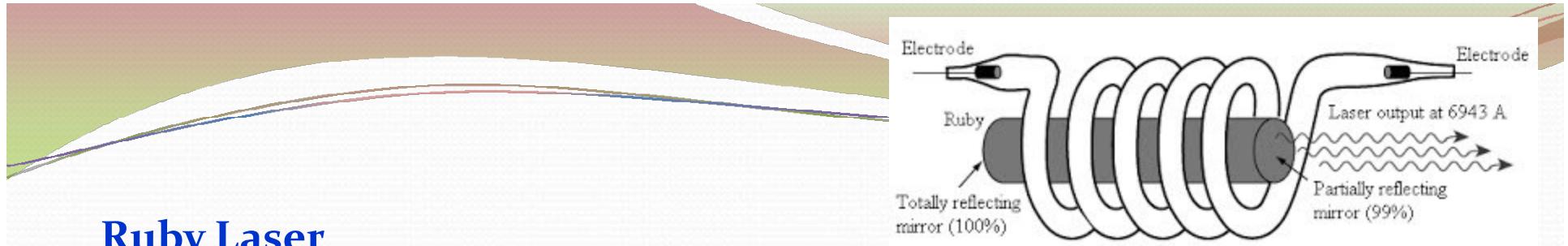
- Optical Resonator provide positive feedback of photons into the medium
- Optical resonator selects direction in which the light is to be amplified (makes light beam directional), The direction of photons is along optic axis of the pair of mirror.
- Optical cavity builds up photon density to high value through repeated reflections of photons and confines them within the medium.
- Optical cavity selects and amplifies only certain frequencies causing laser output to be highly monochromatic.





# SOLID STATE LASER: RUBY LASER



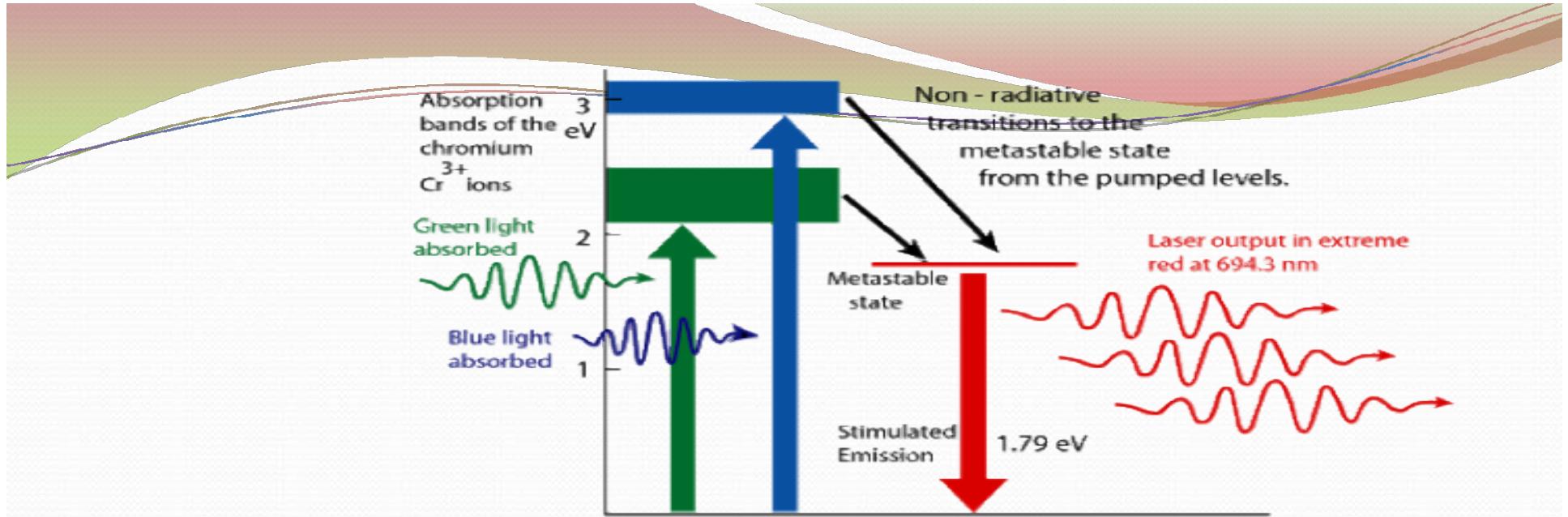


## Ruby Laser

- ❖ Solid State laser
- ❖ Ruby:  $\text{Al}_2\text{O}_3$  Crystal containing 0.05% chromium atoms.
- ❖  $\text{Al}^{3+}$  ions in the crystal lattics are substituted by  $\text{Cr}^{3+}$
- ❖  $\text{Cr}^{3+}$  are active centers and  $\text{Al}_2\text{O}_3$  acts as host.
- ❖ Chromium ions gives pink colour to ruby crystal.

### **Construction:**

- ✓ Ruby crystal is taken in the form of Cylindrical rod of dimension Length:4cm and Diameter 1cm.
- ✓ Ends of ruby crystal are grounded and polished to make end facets parallel and perpendicular to axis of rod.
- ✓ One face is silvered to make 100% reflecting whereas other face is partially silvered to make semitransparent.
- ✓ Rod is surrounded by helical Flash Lamp filled with Xenon.
- ✓ It produces flashes of white light.
- ✓ System is cooled with the help of coolant.



## Working

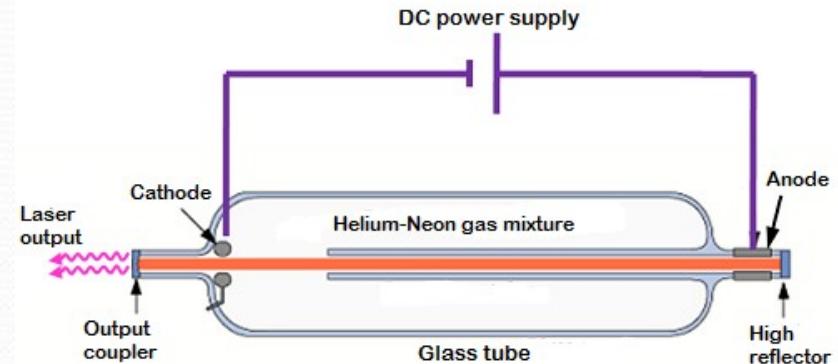
- Ruby Laser Forms three level system
- Xenon Flash lamp generates intense burst of white light for few milliseconds
- The green and blue component of spectrum is absorbed by  $\text{Cr}^{3+}$  ions making transition to  $E_3$  Bands
- Exited levels are unstable and atoms loose there energy ( $E_3 - E_2$ ) to the crystal lattice and undergo non-radiative transitions.
- $E_2$  is a metastable state.
- Population inversion is achieved between  $E_2$  and  $E_1$  Energy state.
- Spontaneously emitted photon initiates stimulated emissions.
- Photons travelling along axial directions are repeatedly reflected and amplified.
- The output beam is red in colour and corresponds to wavelength 6943 Å.

# Problems

## Question 1

Find the ratio of population of the two states in helium neon laser that produces wavelength of  $6328 \text{ \AA}$  at  $27^\circ\text{C}$ .

# Helium Neon Laser

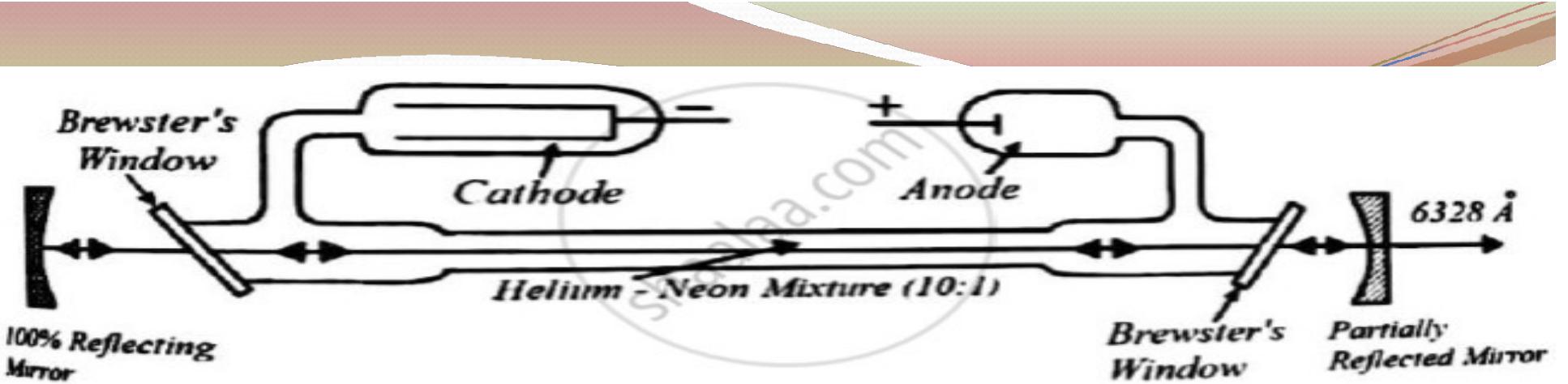


A helium-neon laser, usually called a He-Ne laser, is a type of small gas laser. He-Ne lasers have many industrial and scientific uses, and are often used in laboratory demonstrations of optics.

He-Ne laser is a four-level laser.

Its usual operation wavelength is 632.8 nm, in the red portion of the visible spectrum.

It operates in Continuous Working (CW) mode.



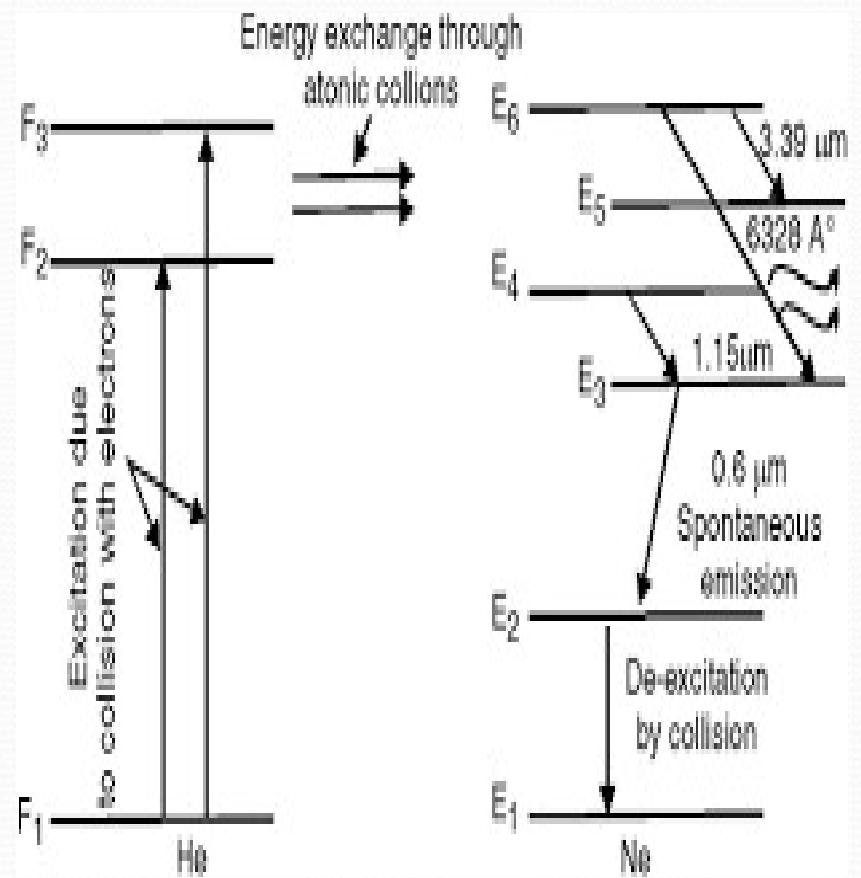
Helium Neon laser is a gas laser.

### Construction

- Consist of long discharge tube of length 50cm and diameter 10cm
- The tube is filled with the mixture of helium and neon gas in the ratio 10:1
- Electrodes are connected to high voltage power supply to produce discharge in gas
- The tube is sealed at its two ends
- The distance between two mirrors is adjusted such that  $L=m\lambda/2$  and it supports standing wave pattern.

## Working

- Employs four level pumping scheme
- Neon atoms are active centers and role of helium atoms is to excite neon atoms too create population inversion.
- When power is switched on electric field ionizes some of the gas atoms.
- Electrons and +vely charged ions moves towards anode and cathode respectively
- Energetic electrons excite helium atoms through collisions to exited levels  $f_2$  and  $f_3$  which lies 19.81 and 20.61 eV above ground level
- These two states of helium are metastable states and atoms cannot return to ground state spontaneously
- The excited helium atoms transfer there energy to neon atoms through collision
- Such energy transfer can take place when colliding atoms have identical energy states.
- The  $E_6$  (20.61 eV) energy level  $E_4$  (18.71 eV) energy level of neon atoms nearly coincide with  $F_2$  and  $F_3$  of helium atoms
- $E_6$  and  $E_4$  energy states of neon are metastable states
- Successive collisions increase the population of  $E_6$  and  $E_4$  levels
- $E_5$  and  $E_3$  levels of neon atoms are sparsely populated.



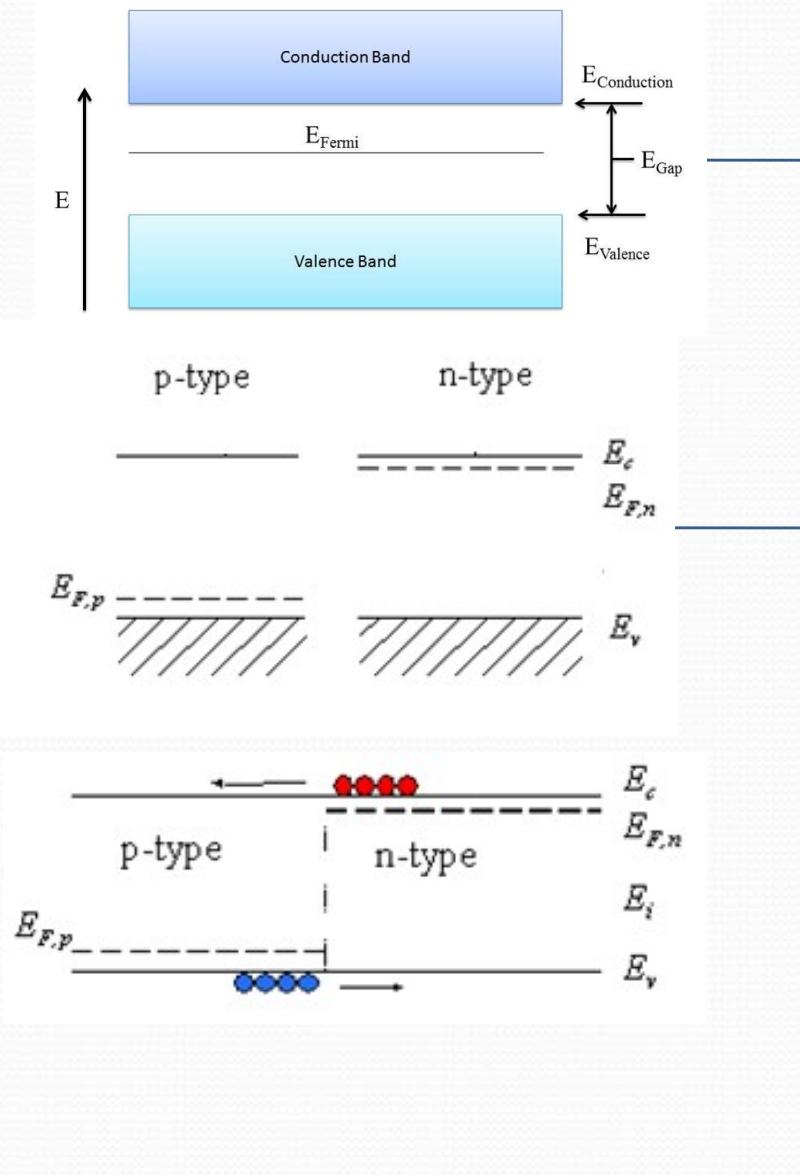
## Possible Transitions

$E_6 \longrightarrow E_3$  transition: generates laser beam of red colour of wavelength 6328A

$E_4 \longrightarrow E_3$  transition: Produces infrared laser beam of wavelength 11500A

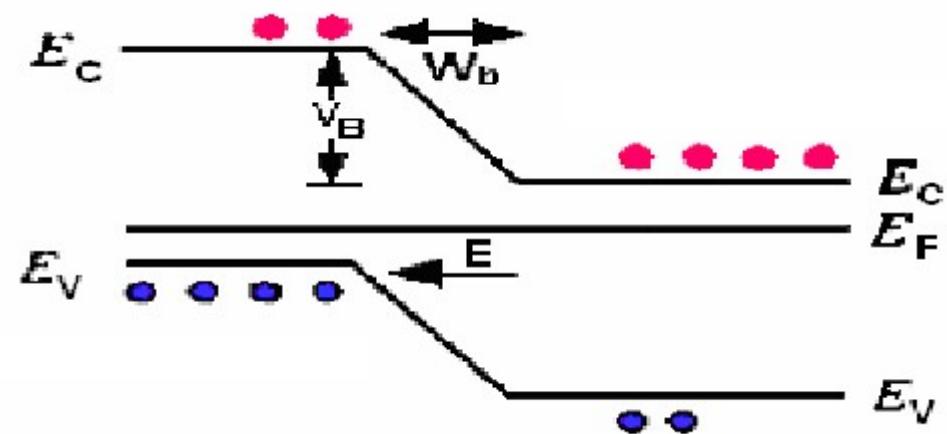
$E_6 \longrightarrow E_5$  transition : laser beam of wavelength 33900A

# PN Junction Diode (Band Bending)

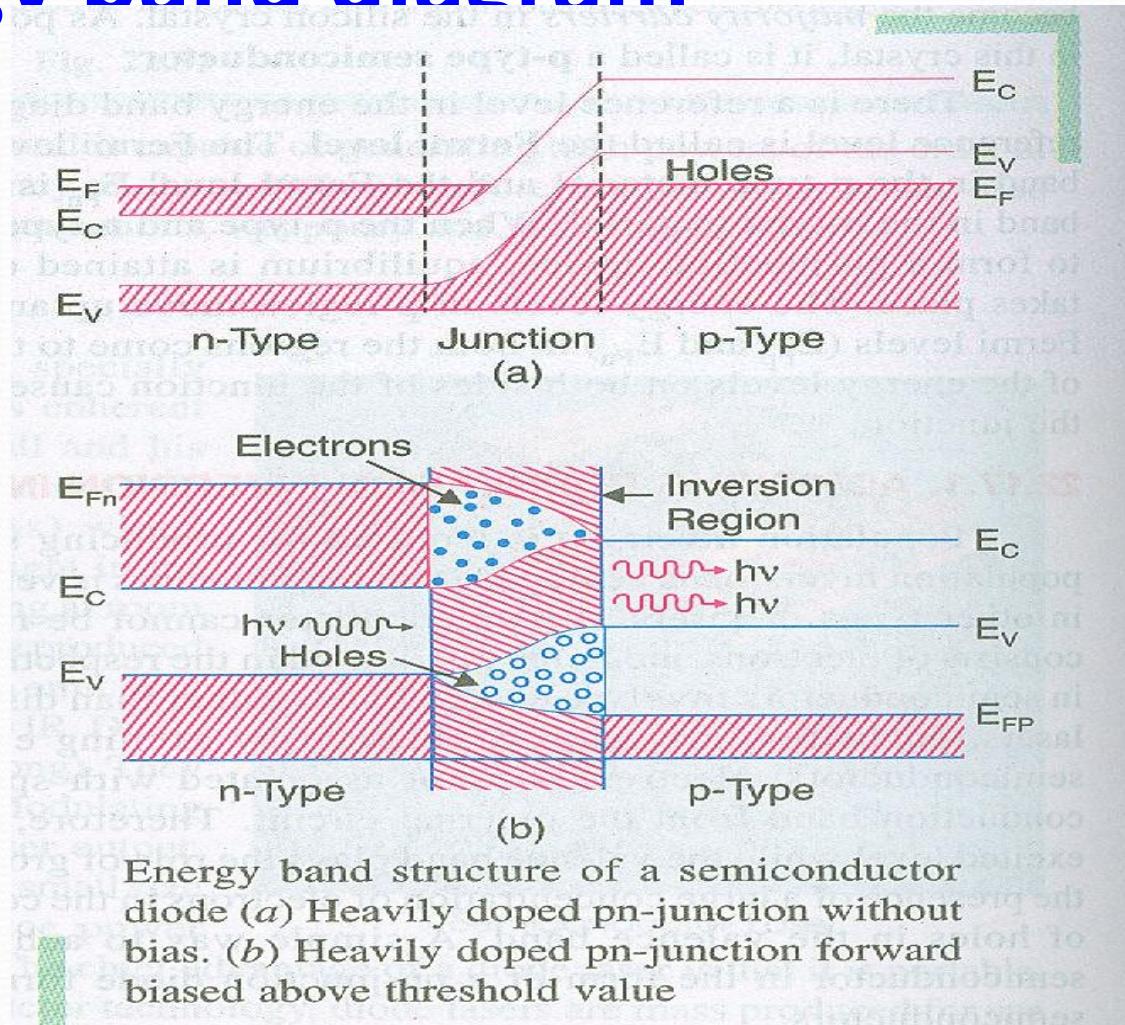


Band structure of Intrinsic Semiconductor

Band structure of P-type and N-type material



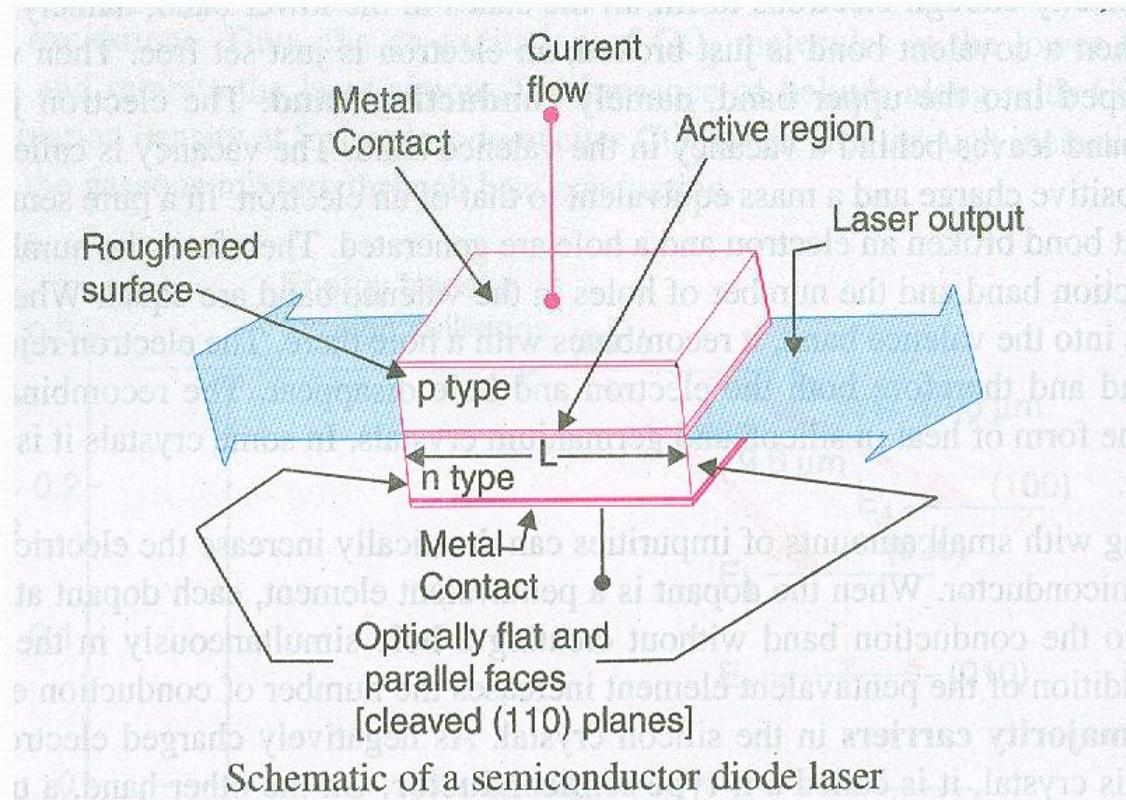
# Energy band diagram



# Introduction

- Laser diode is similar in principle to an LED.
- The most common semiconductor material that has been used in lasers is gallium arsenide(GaAs).
- Stimulated and organized photon emission occurs when two electrons with the same energy and phase meet. The two photons leave with the same frequency and direction.

# Construction

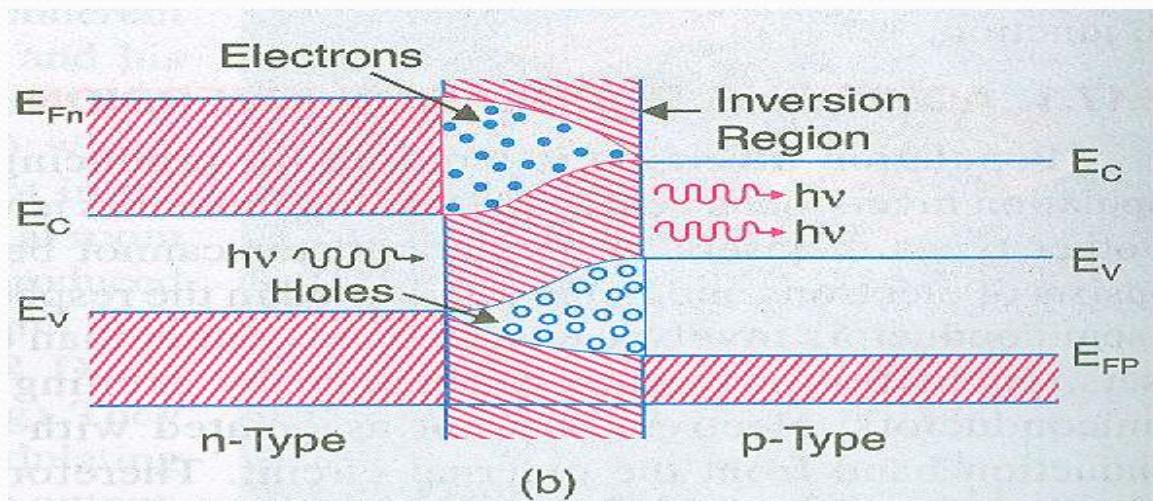
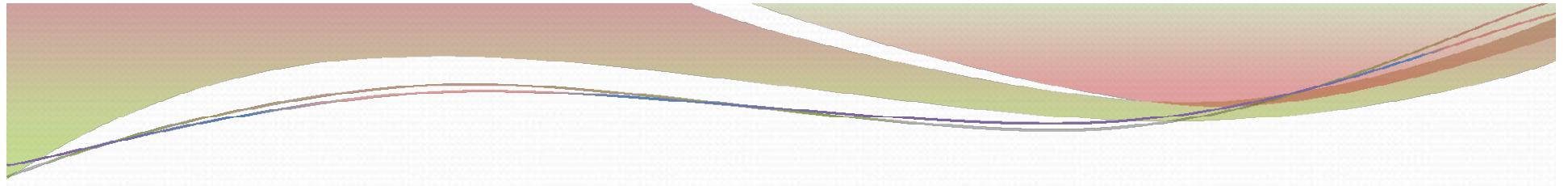


# Laser Diode Working

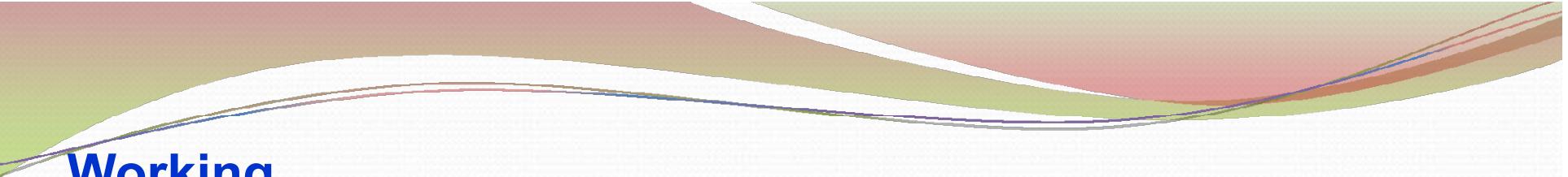
An adequate forward bias is required to develop injection carriers across a junction to initiate a population inversion between energies at VB and energies at CB.

Pumping: Forward diode current.

The process is called *injection pumping*.



Energy band structure of a semiconductor diode (a) Heavily doped pn-junction without bias. (b) Heavily doped pn-junction forward biased above threshold value



## Working

- On P-side  $E_F$  is in the valence band (VB)
- On the N-side  $E_F$  is in the conduction band (CB).
- Energy levels up to the fermi level are occupied by electrons.
- When there is no applied voltage the fermi level is continuous across the diode.

## Pumping Mechanism

- When junction is forward biased, electrons and holes are injected into the junction region in high concentration
- Charge carriers are pumped by DC voltage source
- When diode current reaches threshold value, the carrier conc. In the junction region will rise to very high value

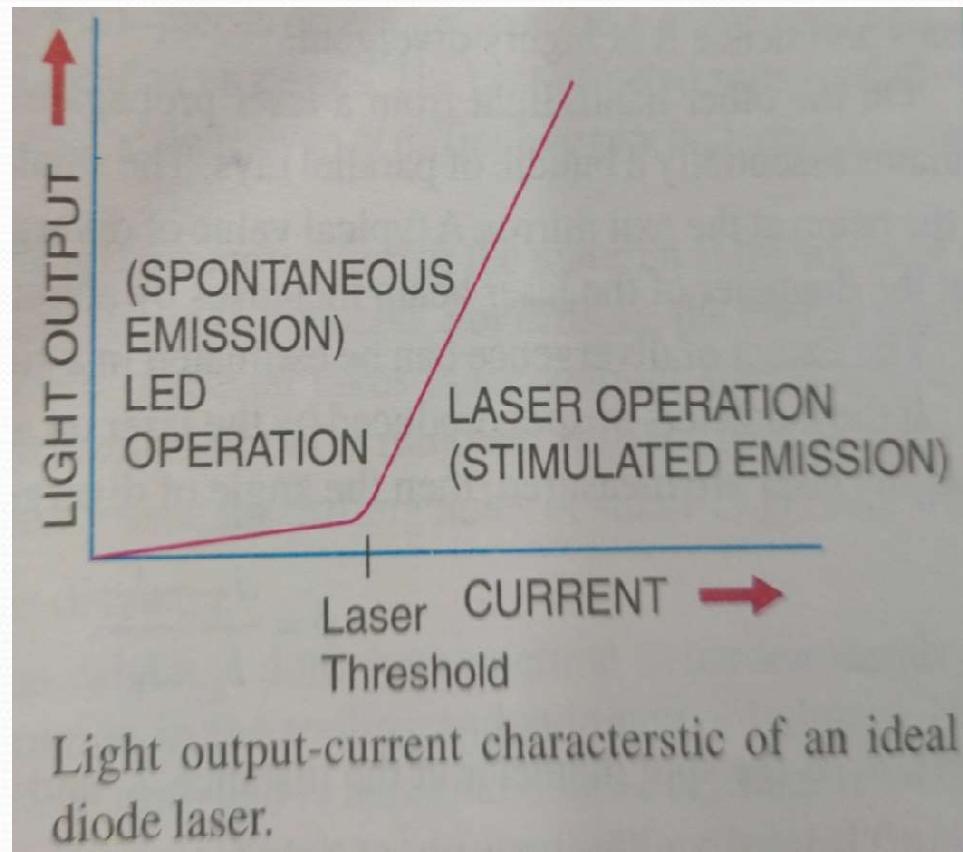
## Population Inversion

- When forward biased, the narrow depletion region contains large number of electrons in conduction band and large number of holes in valence band.
- This represents condition of population inversion.
- *The narrow zone in which population inversion occurs is called as inversion region or active region.*

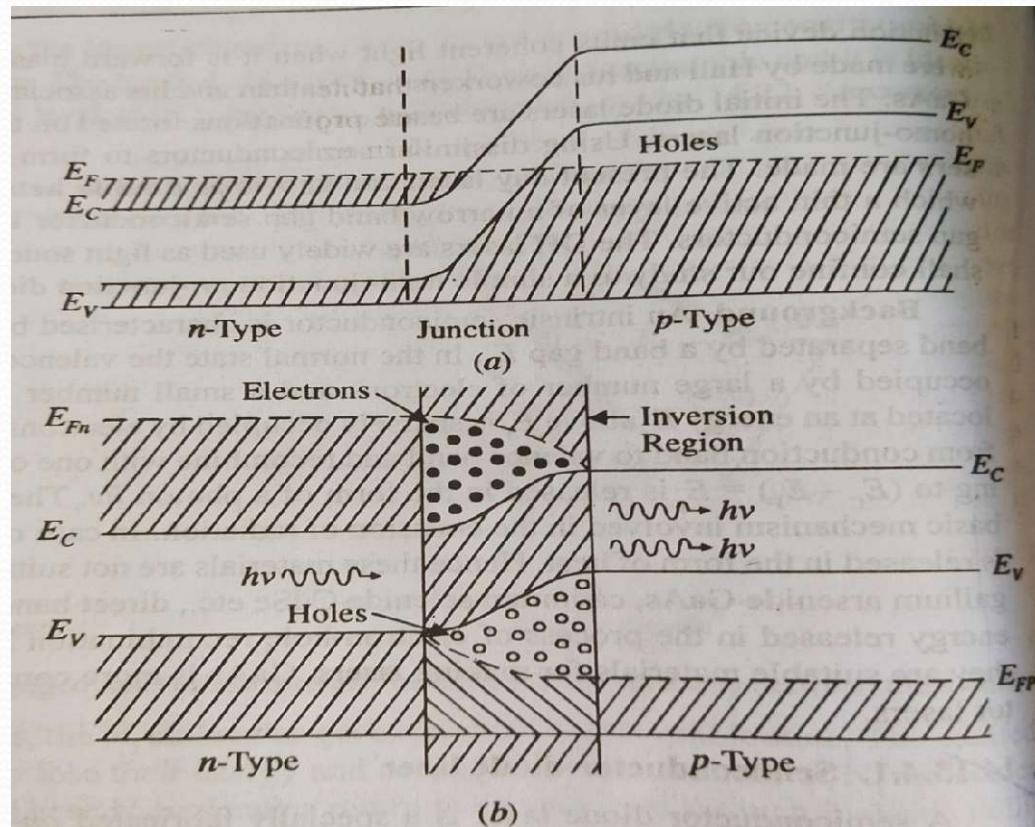
## Lasing

- electron and hole pair recombine to emit photon.
- Spontaneously emitted photon initiates the stimulated emissions
- Stimulated electron hole recombination produces coherent light.

# Output characteristics of ideal Laser Diode



# Energy Band Diagram Of semiconductor diode at equilibrium and forward bias



**Fig. 14.24.** Energy band structure of a semiconductor diode (a) Heavily doped  $pn$ -junction without bias. (b) Heavily doped  $pn$ -junction forward biased above threshold value.

# Nd:YAG Laser

- Four level, solid state laser
- Yttrium Aluminium Garnate(YAG) acts as host material
- $\text{Y}^{3+}$  ions in the crystal lattics are substituted by  $\text{Nd}^{3+}$
- $\text{Nd}^{3+}$  are active centers and YAG acts as host.

# Construction

- ❖ Consist of elliptical cylindrical reflector housing the laser rod.
- ❖ Laser rod is placed at one focus and krypton flash lamp is placed at another focus
- ❖ The light leaving one focus will pass through another focus after reflection from silvered surface
- ❖ Thus entire flash lamp radiation gets focused on the laser rod.
- ❖ The two ends of laser rod are silvered and polished to make resonator cavity.

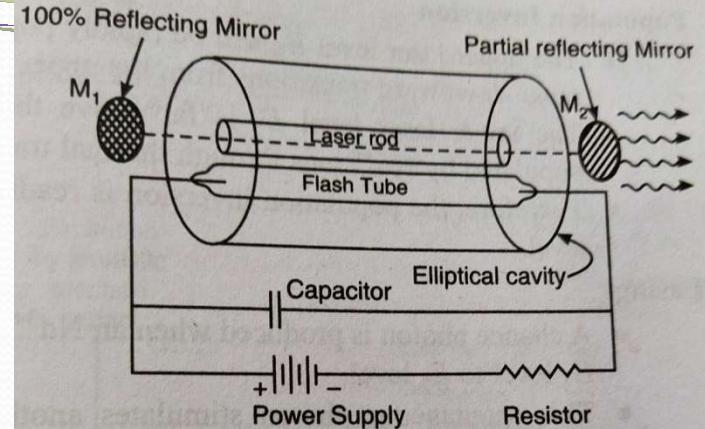
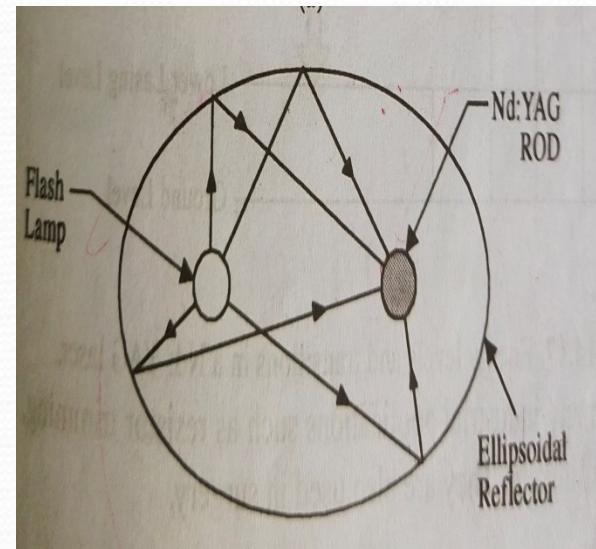
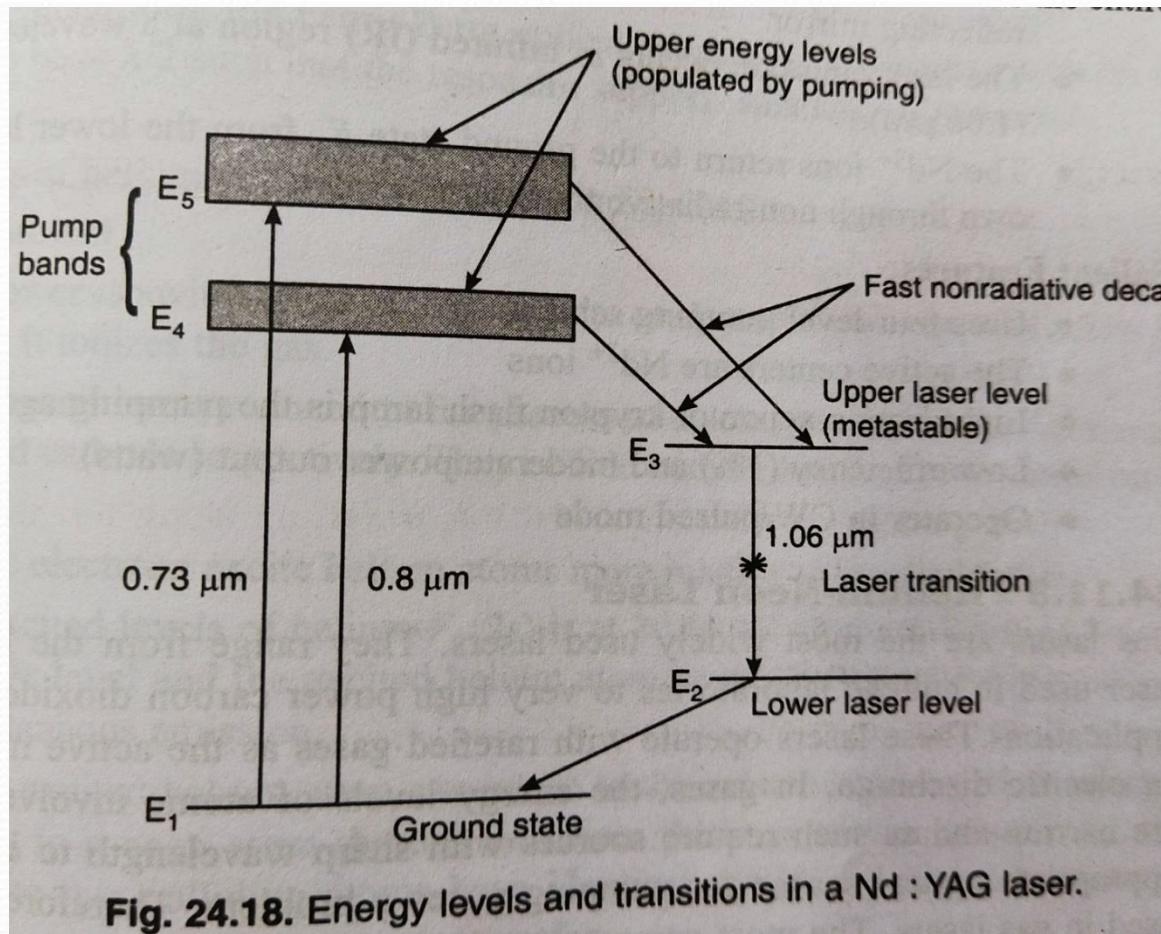


Fig. 24.17. Schematic of a Nd:YAG Laser



# Energy level transition

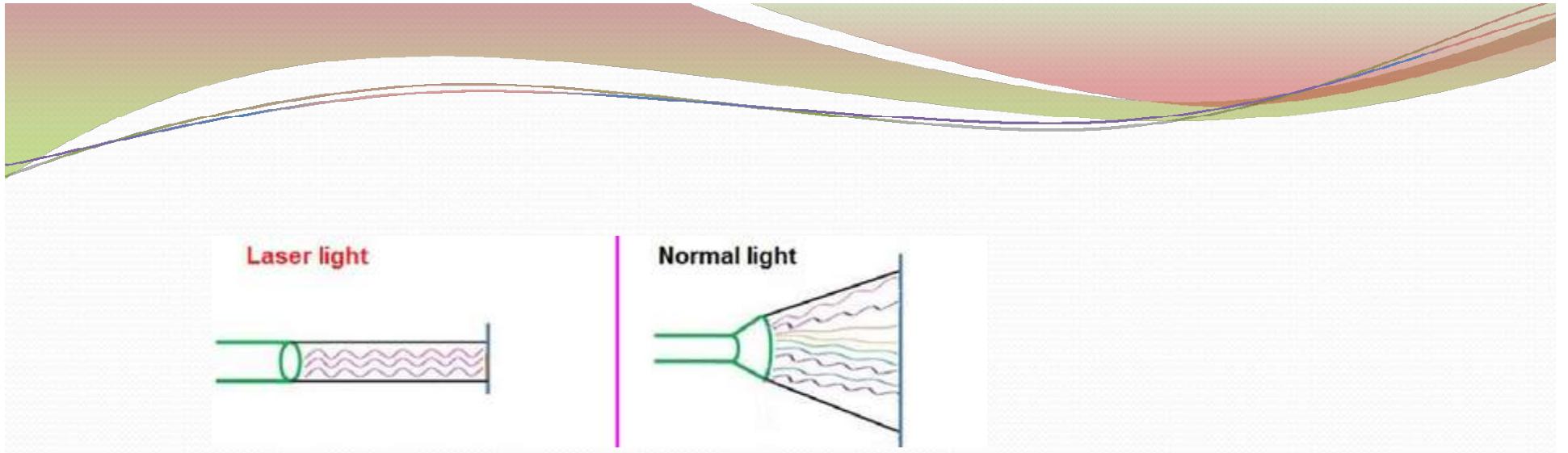


## Pumping Mechanism

- ❖ Crypton flash lamp is switched on, the  $\text{Nd}^{3+}$  ions are exited to the upper energy bands  $E_4$  and  $E_5$
- ❖  $\text{Nd}^{3+}$  ions make non radiative transitions to energy state  $E_3$ ,  $E_3$  is metastable state
- ❖ Population inversion is achieved between  $E_3$  and  $E_2$  energy states of neodymium ions.
- ❖ The laser emission occurs in infrared region at the wavelength of 10,600 Å (1.06 μm)

# Laser Beam Characteristics

- Directionality
- Negligible Divergence
- High Intensity  
 $I=P/A$
- High Degree of coherence
- High Monochromaticity



S.No	Ordinary light	Laser beams
1	In ordinary light the angular spread is more.	In laser beam the angular spread is less.
2	They are not directional.	They are highly directional.
3	It is less intense	It is highly intense
4	It is not a coherent beam and is not in phase.	It is a coherent beam and is in phase
5	The radiation are polychromatic	The radiations are monochromatic
6	Example: Sun light, Mercury vapor lamp	He- Ne Laser, Co <sub>2</sub> laser

# Problems

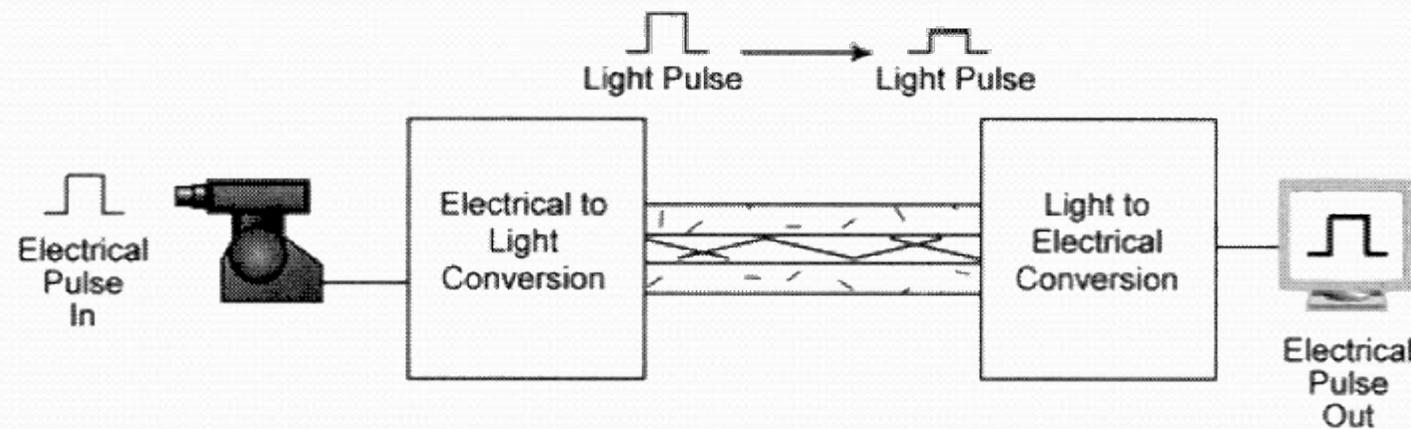
## Question 1

Find the intensity of a laser beam of 10mW power having diameter 1.3nm. Assume intensity to be uniform across the beam.

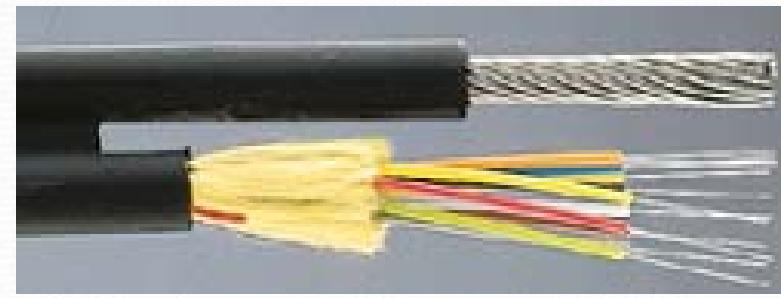
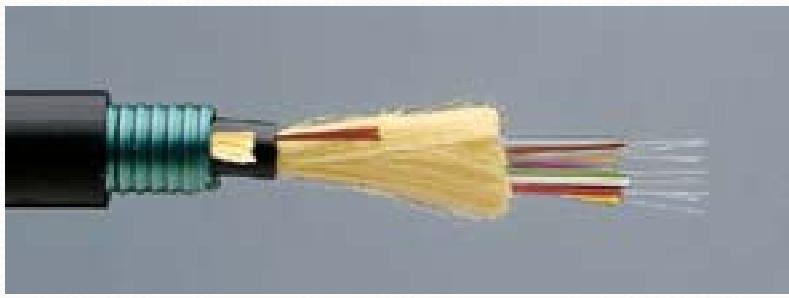
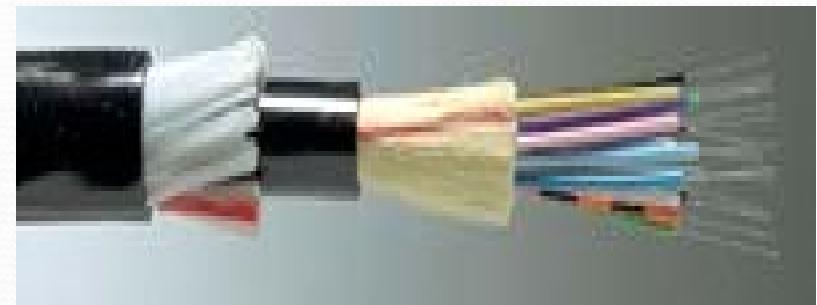
## Question 2

A laser beam can be focussed on an area equal to the square of its wavelength ( $\lambda^2$  ). For a He-Ne laser,  $\lambda=6328\text{A}$ . If the laser radiates energy at the rate of 1 mW, find out the intensity of focussed beam.

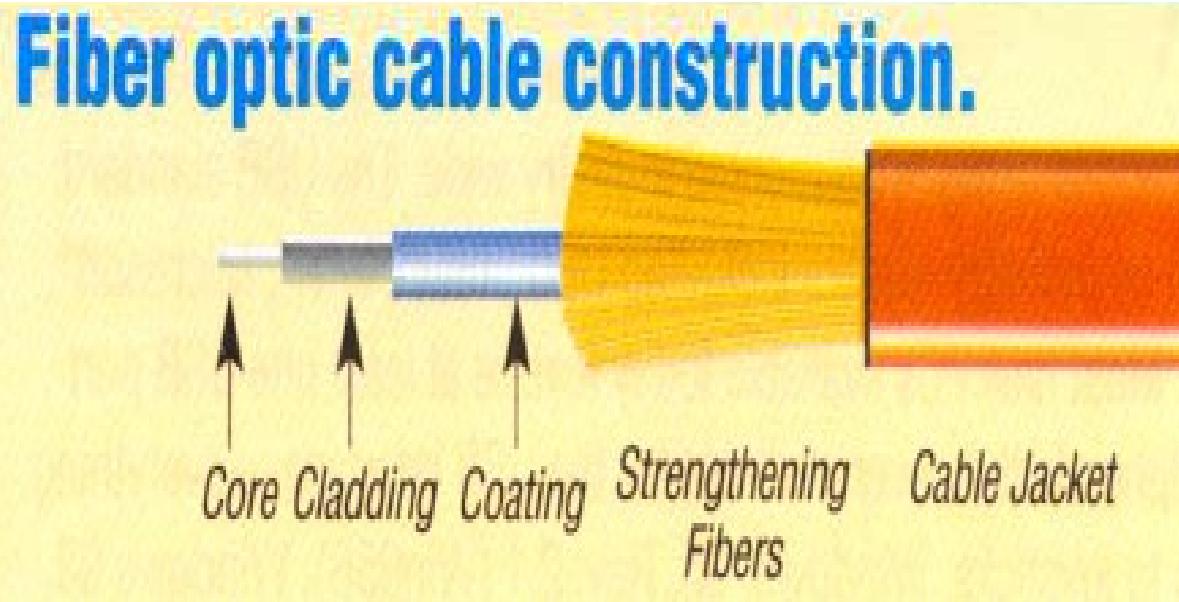
# Signal conversion

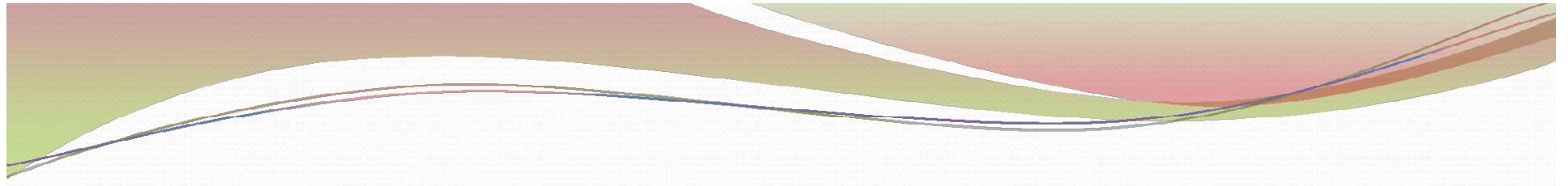


# Optical fiber

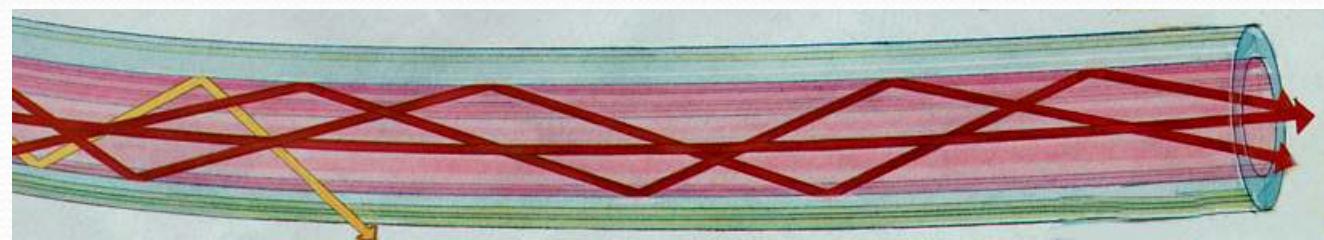
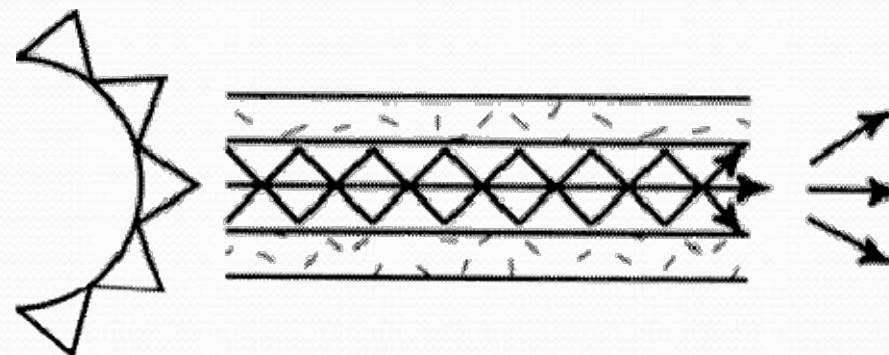


# Fiber structure

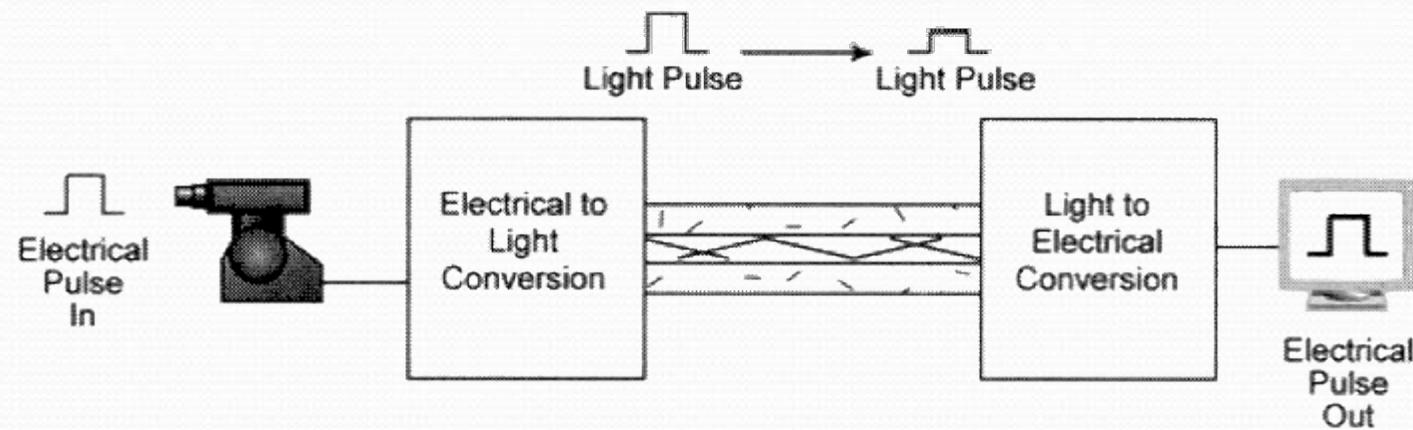




# Wave propagation



# Signal conversion



## **Unit 3**

- **Laser Physics**

Introduction to Lasers, Laser and Ordinary Light, Laser beam Characteristics, Spontaneous and Stimulated emissions of radiations, Thermal equilibrium, Conditions for Light Amplification, Population inversion, Pumping ( Three level and Four Level Pumping), Optical Resonator, Ruby Laser, He-Ne Laser, Semiconductor Laser, Nd-YAG Laser, Engineering Applications of Laser ( Fiber Optics, Laser Material Interaction)